# Nano-Micro Letters

# REVIEW



# Lead-Free Perovskite Materials for Solar Cells

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# HIGHLIGHTS

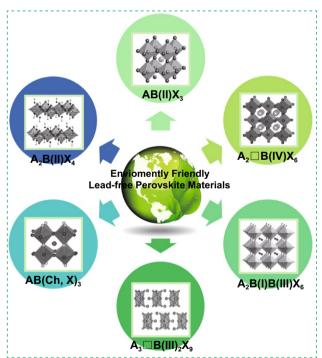
• The toxicity issue of lead-based halide perovskites hinders theirs large-scale commercial applications in solar cells.

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- A variety of non- or low-toxic perovskite materials have been used for development of environmentally friendly lead-free perovskite solar cells, some of which show excellent optoelectronic properties and device performances.
- At present, more new lead-free perovskite materials with tunable optical and electrical properties are urgently required to design highly efficient and stable lead-free perovskite solar cells.

**ABSTRACT** The toxicity issue of lead hinders large-scale commercial production and photovoltaic field application of lead halide perovskites. Some novel non- or low-toxic perovskite materials have been explored for development of environmentally friendly lead-free perovskite solar cells (PSCs). This review studies the substitution of equivalent/ heterovalent metals for Pb based on first-principles calculation, summarizes the theoretical basis of lead-free perovskites, and screens out some promising lead-free candidates with suitable bandgap, optical, and electrical properties. Then, it reports notable achievements for the experimental studies of lead-free perovskites to date, including the crystal structure and material bandgap for all of lead-free materials and photovoltaic performance and stability for corresponding devices. The review finally discusses challenges facing the successful development and commercialization of lead-free PSCs and predicts the prospect of lead-free PSCs in the future.

**KEYWORDS** Solar cells; Perovskite; Lead-free; First-principles calculation; Photovoltaic



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## **1** Introduction

As a major driving force of the world today, traditional fossil fuels have been essential from the first industrial revolution. Although previous industrial revolutions have brought human society into an unprecedented boom era, they have simultaneously caused tremendous energy and resource consumption and aggravated the contradiction between human and nature, making us have to pay a huge environmental price and ecological cost. With the fast development of world's economy and social productive forces, the requirement of energy has also been growing rapidly and the traditional fossil energy has been incapable of meeting our demands. So entering the twenty-first century, humanity has been facing unprecedented challenges of global crises of energy and resource, environment, ecology, and climate change. All of these issues have initiated the fourth industrial revolution, namely the green industrial revolution. At this time, solar energy as the initial source of all energy inevitably becomes new support for human and social development due to its advantages of pollution-free, renewability, huge energy, and so on. Optoelectronic conversion as one of the major utilizations of solar energy has been widely researched in the past several decades, and solar cells belong to the most important type of optoelectronic converters. The development of low-cost, high-efficiency solar cells has become a central issue in recent years. And perovskite solar cells (PSCs), as a promising class of solar cells family, have attracted intensive attention in the past decade due to high absorption coefficient, excellent bipolar charge mobility, long carrier diffusion length, low exciton binding energy, low trap state density, and tunable bandgap.

The power conversion efficiency (PCE) of PSCs based on lead (Pb) perovskites has been dramatically improved from the initial 3.8% to recently certified value of 25.2% [1-24]. However, there exist unavoidable shortcomings in these Pb-based high-efficiency PSCs (e.g., MAPbI<sub>3</sub>, FAPbI<sub>3</sub>, Cs<sub>0.05</sub>FA<sub>0.85</sub>MA<sub>0.10</sub>Pb(I<sub>0.97</sub>Br<sub>0.03</sub>)<sub>3</sub>), that is, the element lead is toxic to the environment and organisms and difficult to discharge from the body. Research indicates that the contamination of lead ions to soil and water sources is permanent and generates a very serious negative impact on human, animal, and plant survival [25–34]. The human's nervous, digestive and blood systems eventually show functional disorders in the case of lead poisoning since lead can enter human's body, bind with enzyme and finally store in soft tissues and bones such as spleen, kidney, liver, and brain through blood circulation. Generally, most people show lead toxic symptoms when lead intake reaches about 0.5 mg/day [25–27]. Therefore, to guarantee human's safe and pollutionfree natural environment it is necessary to develop some non- or low-toxic metal ions to replace lead as perovskite absorbers of PSCs [28–34].

Generally, metal halide perovskites have a universal chemical formula of ABX<sub>3</sub>, where A is an organic cation, B is a metal cation and X is a halogen anion [35–55]. Here, the organic cation usually includes methylammonium (MA), formamidinium (FA), Cs, or their mixture, and the halogen anion consists of Cl, Br, I or their mixture. For B, previous work has showed that less toxic ions like  $Sn^{2+}$ ,  $Bi^{3+}$ ,  $Ge^{2+}$ ,  $Sb^{3+}$ ,  $Mn^{2+}$ , and  $Cu^{2+}$  could be used as an alternative ion to Pb<sup>2+</sup> in perovskites to constitute a new lead-free perovskite structure [56–63]. The introduction of these metal cations not only increases the diversity of perovskite species, but also enhances environmentally friendly features of PSCs.

This review mainly focuses on various lead-free perovskite materials and related solar cell applications by summarizing recent work about theoretical bases and experimental studies of those lead-free perovskites. Specifically, it summarizes the replacement of Pb with other possible isovalent and heterovalent elements proposed recently. Herein, the isovalent elements consisting of Sn (II), Ge (II) and divalent transition metals (e.g., Cu, Fe, Zn), and the heterovalent elements containing Bi(III), Sb (III), Sn (IV), Ti (IV) and double cations of Ag(I)Bi(III) are summarized. The crystal structure and bandgap for all of lead-free materials and their corresponding photovoltaic performance and stability are included. And by comparing various types of lead-free perovskite materials, we finally predict development prospects of lead-free perovskite materials in the future.

# 2 Theoretical Bases of Lead-Free Hybrid Perovskites

First-principles calculation based on density functional theory (DFT) is a modeling method for simulating the electronic structures of many-body systems from atomicscale quantum mechanics. This method has been used as an important tool for the study of lead-free perovskites [64, 65]. Electronic structures of various lead-free perovskites were calculated by researchers to simulate their electron/ hole effective masses, theoretical absorption spectra, carrier mobilities, bandgaps, and other properties related to their potential solar cell applications by first-principles calculations in order to find the optimal MAPbI<sub>3</sub> substitute [67-70]. Generally speaking, there exist a variety of options of exchange-correlation functions in DFT calculations, which will qualitatively affect the result of DFT calculations. In the past research work, researchers often chose local density approximation (LDA) and generalized gradient approximation (GGA) functionals. Although their functions are relatively simple, the calculation results are generally more reliable. But this does not mean that there are no problems. LDA and GGA exhibit serendipitous cancellations between their exchange-correlation parts, which lead to unphysical electron self-interactions. This result further causes the local (LDA) and semilocal (GGA) functions to essentially underestimate the bandgaps of solids by 30–100% [67, 68]. To solve such problems, methods/functions including the many-body perturbation (GW) approximation [65], timedependent DFT (TDDFT) [66], PBE0, HSE03, and HSE06 hybrid functionals [64-70], and more recent delta selfconsistent-field method have been developed and applied to recent theoretical calculations of lead-free perovskites. It is worth emphasizing that in the presence of heavy atoms, spin-orbit coupling (SOC) must be included in the calculation to achieve a more accurate prediction of the electronic structure.

So far, researchers have already had a certain understanding of the lead-free perovskite system after several years of targeted research. The core of research on lead-free perovskite materials is the replacement of Pb element. Researchers have screened out a series of elements that could replace Pb through theoretical calculations (Fig. 1).

Filip et al. considered stability and desired bandgap as two concurrent prerequisites for suitable candidates of lead-free perovskites [66]. They used randomly displaced structures (atom positions and lattice parameters) to investigate the stability of possible lead-free perovskites. Making the stability and desired calculated bandgap as two concurrent conditions, the crystal structure retains the perovskite geometry after relaxation of the shaken configurations, and the relativistic bandgap is smaller than 2.0 eV. Finally, they identified 10 compounds out of 248 candidates for possible solar cell applications with high-throughput screening, as shown in Fig. 1. After calculation, AMgI<sub>3</sub> exhibited as a promising candidate with tunable bandgap between 0.9 and 1.7 eV (1.7 eV for CsMgI<sub>3</sub>, 1.5 eV for CH<sub>3</sub>NH<sub>3</sub>MgI<sub>3</sub> and 0.9 eV for CH(NH<sub>2</sub>)<sub>2</sub>MgI<sub>3</sub>) and low electron effective mass, which is caused by exceptionally dispersive conduction bands [66]. Therefore, Filip et al. deduced that the substitution of Pb by Mg was theoretically feasible to reduce the toxicity of metal halide perovskites without losing solar cell efficiency substantially. In subsequent research work, the researchers have also proved that Cu, Ag, Bi and Sb can also replace Pb to form perovskites (Fig. 1) [62–66].

In addition, it is possible to use valence state replacement to select suitable non-toxic elements by using the first-principles calculation [59, 64-75]. Usually, as shown in Fig. 2, we can replace the Pb element with either homovalent elements such as Sn, Ge, and Cu, or heterovalent elements such as Sb and Bi. To maintain the charge neutrality, the heterovalent replacement can be divided into three subcategories: cation splitting, mixed valence anion and ordered vacancy. Cation splitting is to form a double perovskite structure with a chemical formula of A<sub>2</sub>B(I)B(III)X<sub>3</sub> by splitting Pb into a combination of monovalent and trivalent cations. Introducing mixed valence anions is the case with a single valence cation but two valence anions, whose general chemical formula is  $AB(Ch, X)_3$ , where Ch represents a chalcogen element and X represents a halogen element. The perovskite can maintain electrical neutrality via forming ordered vacancies. Such substitutions can also be divided into two types: the B(III) compounds with a formula of  $A_3 \Box B(III) X_0$ and the B(IV) compounds with a formula of  $A_2 \Box B(IV) X_6$ . Here, the sign of  $\Box$  indicates vacancies. However, the formation of vacancies cuts the original 3D perovskite structure into a low dimension crystal structure, thereby reducing the electronic dimension and then affecting the optoelectronic performance [67].

Researchers have conducted a lot of theoretical studies on the Pb replacement with various elements, e.g., Sn, Ge, and Bi [57–62]. These theoretical studies reveal the advantages and disadvantages of different lead-free perovskite materials. In the substitution of homovalent elements, take Snbased perovskite MASnI<sub>3</sub> as an example. In the process of studying the optoelectronic properties of MASnI<sub>3</sub> using the GW + SOC method, the researchers found that compared with MAPbI<sub>3</sub>, MASnI<sub>3</sub> showed a stronger *s-p* antibond coupling near the maximum value of the valence band (VBM) [68]. This phenomenon is due to the fact that the Sn 5s lone pair is shallower and more active than the Pb 6s lone pair.

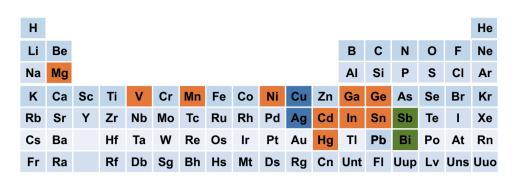


Fig. 1 Potential elements to substitute Pb. The orange shading on the periodic table marks the screened elements by Filip et al. that can replace Pb. The green shading of the VA group heterovalent elements and the blue shading of transition metal elements have also been calculated or proved to substitute Pb. (Color figure online)

In addition, because of much weaker SOC, the Sn 5p orbital is shallower and less dispersive than the Pb 6p orbitals. As a result, compared to MAPbI<sub>3</sub>, the bandgap of MASnI<sub>3</sub> is reduced. Unfortunately, defect calculations indicated that the high-energy Sn 5s<sup>2</sup> state makes the Sn-I bond easy to break, forming high-density Sn vacancies, resulting in an excessively high defect density  $(> 10^{17} \text{ cm}^{-3})$  in the Sn-based perovskite [68]. Similar to Sn-based perovskite, theoretical calculations by Ming et al. indicated that the Ge vacancy in Ge-based perovskite is the dominant defect with shallow transition levels and rather low formation enthalpy, which yields high-density holes, particularly at Ge-poor synthesis conditions [33]. At the same time, Sun et al. pointed out that the stability of MAGeI<sub>3</sub> is better than that of MASnI<sub>3</sub> based on the calculation of the formation energy of the compound. In addition, they calculated the electronic structure and improved bandgap results through the hybrid function HSE06 and the spin-orbit coupling [36]. The calculated band structure showed that the bottom of the conduction band and the top of the valence band are very dispersed, which corresponds to low electron/hole effective masses. These results mean that the replacement of Pb in perovskite by Ge is possible.

In the theoretical study of heterovalent replacement, using  $Cs_3Bi_2I_9$  as an example, the calculations using hybrid Heyd–Scuseria–Ernzerhof (HSE) functional with SOC indicated that  $Cs_3Bi_2I_9$  exhibits an indirect bandgap of 2.10 eV from the  $\Gamma$  point to the K point [40, 51]. Moreover, the defect calculations by Ghosh et al. indicated that most of the defects in  $Cs_3Bi_2I_9$  that have low formation energies generate deep level states in the bandgap, which act as recombination centers [51]. Fortunately, this type of perovskite material has been calculated to own excellent thermodynamic stability.

In addition, the chalcogen-halogen hybrid perovskite  $AB(Ch, X)_3$  was systematically studied by Sun et al. with Ab initio molecular dynamics, GGA functions and DFT-D3 van der Waals scheme [52]. According to relevant calculations, they predicted that MABiSI<sub>2</sub> and MABiSeI<sub>2</sub> have the best bandgap (1.3–1.4 eV) for solar energy collection materials. However, in later studies, Hong et al. combined DFT calculations and solid-state reactions to prove that all proposed AB(Ch, X)<sub>3</sub> perovskites are thermodynamically unstable [34]. Although this result is disappointing, it also reminds us that stability analysis is equally important in the theoretical calculation of the discovery of new lead-free perovskites.

Recently, the theoretical calculation has proved the 0D electronic dimension and larger bandgap of double perovskite  $A_2B(I)B(III)X_6$  with the use of alkali metal B(I) cation [28, 29]. Actually, transition metal B(III) cations with multiple oxidation states and/or partially occupying d or f orbitals are not ideal for the design of photovoltaic absorbers because they may introduce deeper defect states and localized bandedges. Finally, regarding the screening of X anions, it is known that iodides and bromides have the potential of obtaining narrower bandgaps, but they are thermodynamically unstable, while fluorides and chlorides are relatively stable but usually have larger bandgaps [75–78]. The above theoretical research work undoubtedly played a guiding role in the application of new-type lead-free perovskite materials in perovskite solar cells, resulting in a rapid development of this field.

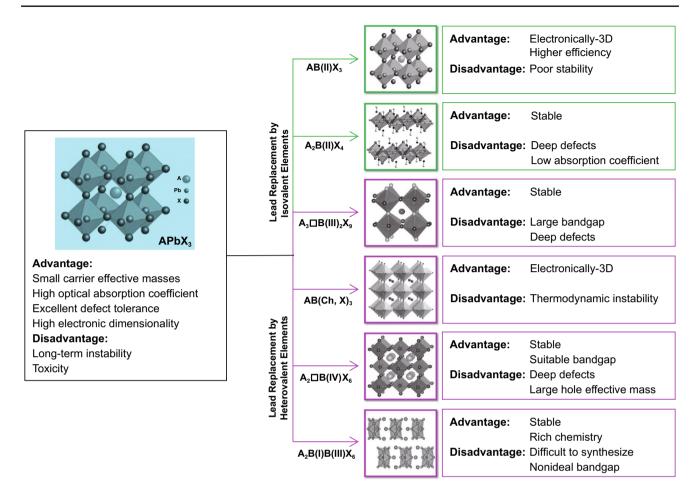


Fig. 2 Schematic illustration of the approaches and consequences of potential Pb replacement

# **3 Experimental Investigation of Various Types of Lead-Free Hybrid Perovskites**

#### 3.1 Lead Replacement by Isovalent Elements

#### 3.1.1 Sn-based Perovskite

As a chemical element of Pb's family (IVA group),  $\text{Sn}^{2+}$  possesses a homologous lone-pair s orbital and similar radius (1.35 Å) to Pb<sup>2+</sup> (1.49 Å); therefore, Sn-based perovskites show superior optoelectronic properties similar with Pb [68, 69]. In addition, they also exhibit narrower optical bandgaps (1.2–1.4 eV) and higher carrier mobilities than the Pb-based counterparts. Moreover, due to intrinsic low toxicity of Sn, the Sn-based perovskite absorbers have become the important candidate for lead-free perovskites and gradually turned into the research hotspot in high-performance lead-free PSCs [68–70]. As a result, the Sn-based perovskites

are more suitable for efficient single-junction solar cell applications. However,  $\text{Sn}^{2+}$  is unstable and easily oxidized to  $\text{Sn}^{4+}$ . The formation of  $\text{Sn}^{4+}$  leads to p-type self-doping in Sn-based perovskites, which will generate numerous Sn vacancies with large background carrier density and rapid recombination of charge carriers [14], leading to serious performance degradation and poor reproducibility of PSCs using Sn-based perovskites as absorbers [26–30].

#### 3.1.1.1 3D Sn-based Perovskite

#### (1) $MASn(I,Br)_3$

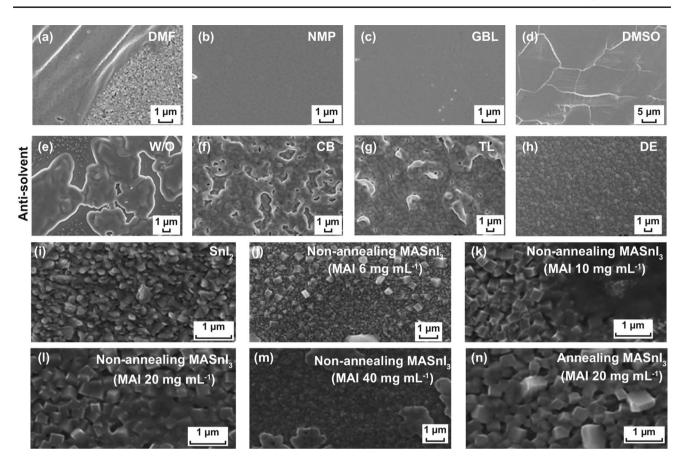
The first MASnIBr<sub>2</sub> perovskite solar cell was realized with a PCE of 5.7% in 2014 [70], whose PCE was then quickly refreshed to 6.4% by Zhao in the same year [71]. In 2015, Umari et al. investigated the optoelectronic properties of MASnI<sub>3</sub> with a more advanced many-body perturbation theory involved with SOC [68]. They found MASnI<sub>3</sub> exhibited a higher charge mobility of  $10^2 - 10^3$  cm<sup>2</sup> V<sup>-1</sup> s<sup>-1</sup> [68, 69], a smaller direct bandgap of 1.1 eV at the  $\Gamma$  point and a higher absorption coefficient of  $1.82 \times 10^4$  cm<sup>-1</sup> in the visible region than MAPbI<sub>3</sub>, whose mobility, bandgap and absorption coefficient of the latter are  $10-10^2$  cm<sup>2</sup> V<sup>-1</sup> s<sup>-1</sup>, 1.5 eV and  $1.80 \times 10^4$  cm<sup>-1</sup>, respectively [56, 70]. These pretty results encouraged researchers to pay more attention to Sn-based perovskites. Interestingly, Sn-based perovskite materials exhibit n-type semiconductor characteristics when the internal Sn<sup>2+</sup> content ratio is high, and p-type semiconductor characteristics when the Sn<sup>4+</sup> content ratio is high. Until now plenty of efforts have been dedicated to development of high-performance and air-stable Sn-based perovskite solar cells [33, 34]. Poor homogeneity and low coverage are critical issues to be solved in Sn-based perovskites, which usually lead to direct contact between the hole-transporting layer (HTL) and the electron-transporting layer (ETL), thus generating low PCEs [70, 72]. Here, film formation methods suitable for Pb-based perovskites tend to become inefficient for Sn-based cases due to a faster crystallization rate of Snbased perovskites [73, 74]; for instance, one-step method with common solvent of N,N-dimethylformamide (DMF) or  $\gamma$ -butyrolactone (GBL) hardly realized smooth Sn-based perovskite films on flat substrates. Hao et al. studied the effect of solvent on the crystallization of MASnI<sub>3</sub> perovskite film and found that adding dimethyl sulfoxide (DMSO) retarded the perovskite crystallization via the formation of a stable intermediate adduct SnI<sub>2</sub>·3DMSO (Fig. 3a), the film formation speed of which was eventually controlled by the evaporation rate of DMSO. As the scanning electron microscopy (SEM) images shown in Fig. 3a-d, the morphologies of MASnI<sub>3</sub> films with DMSO showed the highest coverage and pinhole-free property on mesoporous TiO<sub>2</sub> [74]. Moreover, N-methyl-2-pyrrolidone (NMP) was also investigated as a solvent to further understand the effect of the intermediate phase on the tin perovskite formation process. As a result, a high-quality, pinhole-free CH<sub>3</sub>NH<sub>3</sub>SnI<sub>3</sub> films are achieved using NMP as solvents [73, 74].

Multi-step film formation method was another efficient approach to achieve high-quality Sn-based perovskite films [19, 56, 75, 76]. Schlettwein et al. reported an approach combined thermal evaporation with solution process to fabricate MASnI<sub>3</sub> perovskite films [56, 76]. The SnI<sub>2</sub> layers prepared by vapor thermal deposition could be converted to MASnI<sub>3</sub> by sequentially spin coating MAI solution. The as-acquired sizes of  $MASnI_3$  grains were over 200 nm (Fig. 3i–n) [75]. Moreover, the film morphologies were highly dependent on MAI concentrations. With the increasing concentration of MAI, larger and more uniform  $MASnI_3$  crystals were obtained (Fig. 3i–n). After 10-min thermal annealing, high-quality and dense films were achieved with significantly improved stability. The films remained stable after exposure to air for 90 min under both dark and light conditions.

In addition to the above approaches, Qi et al. invented a method to improve the quality of MASn(I, Br)<sub>3</sub>-based perovskite film. They used co-evaporation and sequential evaporation methods to fabricate MASnBr3 perovskite films with SnBr<sub>2</sub> and MABr as precursors [77]. For co-evaporation, they used a 4:1 MABr/SnBr<sub>2</sub> deposition ratio (0.4:0.1 Å s<sup>-1</sup>) to simultaneously evaporate the two materials, and finally produced a perovskite film with a thickness of about 400 nm. However, solar cells based on this film only showed a low PCE of 0.35% (Fig. 4a). Such a low PCE was resulted from the oxidation of Sn<sup>2+</sup> which restrained the generation of excitons, the carriers diffusion, and the final charge extraction. As a melioration, Qi et al. then employed sequential deposition method to decrease oxidation (Fig. 4b, c) and realized a relatively high PCE of 1.12% because oxidation can be significantly avoided by the top MABr layer [77]. The specific operation is first to deposit a 100-nm film of SnBr<sub>2</sub>, and then to precipitate a following 400-nm film of MABr (Fig. 4d). The as-deposited sample was transferred from the vacuum system to a N<sub>2</sub> glovebox for post-annealing so as to convert the two-layer sample to MASnBr<sub>3</sub> perovskite. Therefore, sequential evaporation approach could be an efficient approach for fabricating high-quality Sn-based perovskites.

#### (2) $CsSn(I,Br)_3$

In 1974, Fisher et al. first synthesized and characterized allinorganic CsSnX<sub>3</sub> compounds [78]. It was not until 2012, Shum et al. reported the application of CsSnI<sub>3</sub> in perovskite solar cell [79]. A black thin film of CsSnI<sub>3</sub> with a bandgap of 1.3 eV was fabricated by alternate depositions of SnCl<sub>2</sub> and CsI on a glass substrate followed by a thermal annealing process. The CsSnI<sub>3</sub> perovskite solar cell exhibited a PCE of 0.9%. Then in 2014, Mathews et al. reported a CsSnI<sub>3</sub> PSC incorporated with SnF<sub>2</sub> to reduce Sn vacancies and obtain a high photocurrent output [71]. The best PCE of 2.02% as well as a short-circuit current density ( $J_{sc}$ ) of

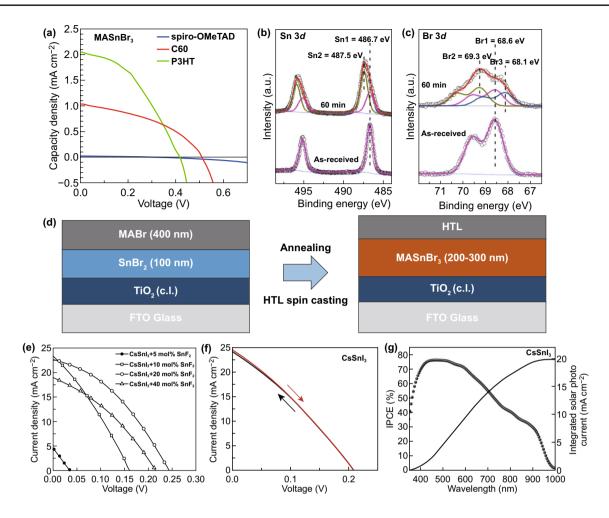


**Fig. 3** SEM images for MASnI<sub>3</sub> layer on mesoporous TiO<sub>2</sub> layer by using **a** DMF, **b** NMP, **c** GBL, and **d** DMSO solvents. Reproduced with permission from Ref. [74]. SEM images for FASnI<sub>3</sub> films obtained from different antisolvent processes: **e** No dripping, **f** CB, **g** TL and **h** DE. Reproduced with permission from Ref. [96]. SEM images of **i** vapor deposited 100 nm SnI<sub>2</sub>, non-annealing MASnI<sub>3</sub> films with **j** 6, **k** 10, **l** 20 and **m** 40 mg mL<sup>-1</sup> MAI precursor solution spin coated and **n** MASnI<sub>3</sub> films with 20 mg mL<sup>-1</sup> MAI precursor solution spin coated followed by annealing at 80 °C for 10 min. Reproduced with permission from Ref. [75]

22.70 mA cm<sup>-2</sup>, an open-circuit voltage ( $V_{oc}$ ) of 0.24 V and a fill factor (FF) of 0.37 was achieved with 20 mol % SnF<sub>2</sub> (Fig. 4e). Moreover, the devices displayed less hysteresis than those counterparts without SnF<sub>2</sub> (Fig. 4f). The incident photon-to-current conversion efficiency (IPCE) data clearly indicated that the onset was extended to 950 nm, which corresponded to 1.3 eV of bandgap (Fig. 4g). In 2015, a detailed study on CsSnX<sub>3</sub> was done by Sabba et al. [80]. Their studies revealed that the CsSnX<sub>3</sub> materials were semiconductors with a strong tendency to self-doping because the oxidation of Sn<sup>2+</sup> to Sn<sup>4+</sup> would generate hole carriers.

It is worth mentioning that  $CsSnI_3$  as a 3D p-type orthorhombic perovskite possesses a bandgap of 1.3 eV [81], a low exciton binding energy of  $18 \times 10^{-3}$  eV [82], and a high optical absorption coefficient of  $10^4$  cm<sup>-1</sup> (comparable to MAPbI<sub>3</sub>) [83]. Therefore, it has the potential to be as

a light absorber for lead-free PSCs. The biggest obstacle that hinders rapid development of CsSnI<sub>3</sub> perovskite solar cell is the instability of CsSnI<sub>3</sub> and the black phase CsSnI<sub>3</sub> could be easily converted to yellow phase CsSnI<sub>3</sub> in atmosphere due to its oxidization [69, 84]. It was reported that the excessive SnI<sub>2</sub> contributed to the improvements of efficiency and stability of CsSnI<sub>3</sub>-based PSCs [85]. The CsSnI<sub>3</sub> films with low defect density and high surface coverage were prepared in a Sn-rich environment or at high temperature. The PCE of the device with a configuration of ITO/CuI/CsSnI<sub>3</sub>/ fullerene/bathocuproine (BCP)/Al increased from 0.75 to 1.5% in the condition of 10 mol % excessive SnI<sub>2</sub>, and  $V_{oc}$ and FF remained good within 20 min under light stability. Although  $J_{sc}$  quickly deteriorated by 10% in the first 50 min,  $J_{\rm sc}$ 's decline rate slowed significantly. The excess of SnI<sub>2</sub> located at the CsSnI<sub>2</sub>/CuI interface formed an interfacial



**Fig. 4** a J-V curves of co-evaporated MASnBr<sub>3</sub> films with different hole transport materials. b Sn 3d and c Br 3d XPS results of MASnBr<sub>3</sub> films as-deposited and after 1 h stored in air. d Fabrication of sequential method for MASnBr<sub>3</sub> films. Reproduced with permission from Ref. [77]. e J-V curves of CsSnI<sub>3</sub>-based PSCs incorporated with different ratios of SnF<sub>2</sub>. f J-V curves of 20 mol % SnF<sub>2</sub>-doped CsSnI<sub>3</sub> devices showing no hysteresis. g IPCE spectrum for 20 mol % SnF<sub>2</sub>-doped CsSnI<sub>3</sub> devices. Reproduced with permission from Ref. [71]

dipole which acted as a hole-transporting layer from  $CsSnI_3$  to CuI owing to a favorable vacuum level shift.

After that, some additives have been introduced into precursors to further improve film quality of  $CsSn(I,Br)_3$ perovskites, which have significantly promoted the performances of  $CsSn(I,Br)_3$  perovskite solar cells [86–90]. Marshall et al. systematically investigated  $CsSnI_3$  perovskite films with different Sn halide additives, such as  $SnF_2$ ,  $SnCl_2$ ,  $SnI_2$ , and  $SnBr_2$  [90]. The films adding  $SnCl_2$  additive had the highest pinhole density and the HTL-free devices with 10 mol %  $SnCl_2$  achieved the highest FF and PCE. Such results were mainly attributed to the formation of ultrathin hole-selective layer of  $SnCl_2$  at the ITO/CsSnI<sub>3</sub> interface. On this basis, doping Br into  $CsSnI_3$  was also proposed. It is noteworthy that the Br-doped  $CsSnI_{3-x}Br_x$  perovskites showed a much higher FF compared to  $CsSnI_3$  due to the appearance of the negligible overlayer of  $CsSnI_{3-x}Br_x$  [80]. The crystal structure was thus changed from orthorhombic ( $CsSnI_3$ ) to cubic ( $CsSnBr_3$ ) with the increase in Br component. The onset of optical bandgap edge was also altered from 1.27 eV ( $CsSnI_3$ ) to 1.37, 1.65, and 1.75 eV for  $CsSnI_2Br$ ,  $CsSnIBr_2$  and  $CsSnBr_3$ , respectively (Fig. 5). Notably,  $CsSnI_2Br$ ,  $CsSnIBr_2$  and  $CsSnBr_3$  were suitable for solar cell applications due to their excellent thermal and air stabilities (Table 1) [80].

#### (3) FASn(I,Br)<sub>3</sub>

Compared to MA<sup>+</sup> and Cs<sup>+</sup>, FA<sup>+</sup> is another extensively investigated organic cation with a relatively larger ionic radius. FASnI<sub>3</sub> is a 3D perovskite with a bandgap of 1.41 eV, which is slightly wider than MASnI<sub>3</sub> (1.30 eV) and CsSnI<sub>3</sub> (1.30 eV) [37] but narrower than Pb-based perovskites (~1.5 eV) [69]. Moreover, the bandgaps of FASnX<sub>3</sub> can be tuned with different halides, e.g., 1.68 and 2.4 eV for FASnI<sub>2</sub>Br and FASnBr<sub>3</sub> [78, 91]. The FASnI<sub>3</sub> material exhibits a threshold charge-carrier density of  $8 \times 10^{17}$  cm<sup>-3</sup> and a charge-carrier mobility of 22 cm<sup>2</sup> V<sup>-1</sup> s<sup>-1</sup> [92]. In addition, FASnI<sub>3</sub> has a similar thermal stability but a lower conductivity with respect to MASnI<sub>3</sub> [93].

Synthesis and characterization of cubic FASnI<sub>3</sub> perovskite were first investigated in 1997 [94]. Until now, most highperformance Sn-based PSCs are mainly based on FASnI<sub>3</sub> materials [95–97] because of their better air stability. This is because the trap density of FASnI<sub>3</sub> (n-type semiconductor) is as low as ~ 10<sup>11</sup> cm<sup>-3</sup>, preventing water and oxygen from entering into the FASnI<sub>3</sub> crystal, which has been experimentally proved by Wang et al. [98]. Therefore, the air stability of the FASnI<sub>3</sub> crystal is higher than MASnI<sub>3</sub> one.

After the first successful incorporation of  $\text{SnF}_2$  into  $\text{CsSnI}_3$ , Mathews group further verified similar effect of  $\text{SnF}_2$  additive on performance enhancements of FASnI<sub>3</sub>-based solar cells.  $\text{SnF}_2$  additive played a similar role in preventing oxidation of  $\text{Sn}^{2+}$  to  $\text{Sn}^{4+}$  and reducing background carrier density, and the FASnI<sub>3</sub> PSC with 20%  $\text{SnF}_2$  finally achieved a PCE of 2.1% [99].

However, it has been proven that a higher amount of  $SnF_2$ induced severe phase separation in the FASnI<sub>3</sub> perovskites films and thus led to performance degradation of solar cells. To solve this issue, Seok et al. introduced pyrazine into DMF/DMSO mixed precursor solution to fabricate highquality FASnI<sub>3</sub> films with high coverage and smooth surface [87]. Since the N atoms in pyrazine can accept lone pairs electrons, pyrazine doping can remarkably restrict the phase separation and effectively reduce Sn vacancies [84], with which a dense, smooth, and pinhole-free FASnI<sub>3</sub> perovskite layer and a pretty good PCE of 4.8% were achieved with high reproducibility. Furthermore, the encapsulated solar cells exhibited good long-term stability, remaining 98% of the initial PCE for over 10-day storage under ambient condition. It is worth mentioning that, in addition to SnF<sub>2</sub> and pyrazine, hydrazine vapor, hydrazine iodide [69], and Sn powder [100] have also been used as antioxidants in Sn-based perovskites in later work. The application of these antioxidants has a similar effect with SnF<sub>2</sub>, that is, to improve the stability and efficiency of Sn-based PSCs by reducing Sn vacancies and background carriers in Sn perovskites.

In addition, some other special materials have also been served as additives to improve the film quality of perovskites and hinder the oxidation of  $\text{Sn}^{2+}$ . For instance, Chen et al. used the bidentate ligand 8-hydroxyquinoline (8HQ) as an additive in the perovskite [101]. The N and O atoms in the 8HQ can simultaneously coordinate with  $\text{Sn}^{2+}$  and greatly inhibit the oxidation of  $\text{Sn}^{2+}$ . Meantime, the formation of complex also improved the quality of FASnI<sub>3</sub> film and reduced defect state-induced non-radiative recombination. Recently, ammonium hypophosphite was introduced into the FASnI<sub>3</sub> perovskite precursor by Yan et al. to suppress the oxidation of  $\text{Sn}^{2+}$  and assist the growth of perovskite grains, resulting in improved perovskite film

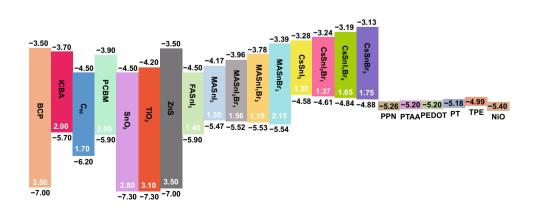


Fig. 5 Energy diagram of common Sn-based perovskites, ETLs and HTLs. Unit: eV

Table 1 Photovoltaic parameters of PSCs based on various Sn-based perovskite absorbers. In the table, c-TiO<sub>2</sub> and m-TiO<sub>2</sub> represent compact and mesoporous TiO<sub>2</sub> layer, respectively

Preparation process	Absorber	Device architecture	$V_{\rm oc}$ (V)	$J_{\rm sc}~({\rm mA~cm^{-2}})$	FF (%)	PCE (%)	References
One-step	MASnI <sub>3</sub>	c-TiO <sub>2</sub> /m-TiO <sub>2</sub> /perovskite/ spiro-MeOTAD/Au	0.68	16.30	48	5.23	[70]
One-step	MASnI <sub>2</sub> Br	c-TiO <sub>2</sub> /m-TiO <sub>2</sub> /perovskite/ spiro-MeOTAD/Au	0.77	14.38	50	5.48	[70]
One-step	MASnIBr <sub>2</sub>	c-TiO <sub>2</sub> /m-TiO <sub>2</sub> /perovskite/ spiro-MeOTAD/Au	0.82	12.30	57	5.73	[70]
One-step	MASnBr <sub>3</sub>	c-TiO <sub>2</sub> /m-TiO <sub>2</sub> /perovskite/ spiro-MeOTAD/Au	0.88	8.26	59	4.27	[70]
One-step	MASnI <sub>3</sub>	c-TiO <sub>2</sub> /m-TiO <sub>2</sub> /perovskite/ spiro-MeOTAD/Au	0.716	15.18	50.07	5.44	[135]
One-step	MASnI <sub>3</sub>	c-TiO <sub>2</sub> /m-TiO <sub>2</sub> /perovskite/ spiro-MeOTAD/Au	0.88	16.8	42	6.4	[82]
One-step	MASnI <sub>3</sub>	c-TiO <sub>2</sub> /m-TiO <sub>2</sub> /perovskite/ spiro-MeOTAD/Au	0.79	13.40	52	5.49	[124]
One-step	$CsSnI_3 + 20\% SnF_2$	c-TiO <sub>2</sub> /m-TiO <sub>2</sub> /perovskite/ spiro-MeOTAD/Au	0.201	27.67	29	1.66	[91]
One-step	$CsSnI_2Br + 20\% SnF_2$	c-TiO <sub>2</sub> /m-TiO <sub>2</sub> /perovskite/ spiro-MeOTAD/Au	0.289	15.06	38	1.67	[91]
One-step	$CsSnIBr_2 + 20\% SnF_2$	c-TiO <sub>2</sub> /m-TiO <sub>2</sub> /perovskite/ spiro-MeOTAD/Au	0.311	11.57	43	1.56	[ <mark>9</mark> 1]
One-step	$CsSnI_{2.9}Br_{0.1} + 20\% SnF_2$	c-TiO <sub>2</sub> /m-TiO <sub>2</sub> /perovskite/ spiro-MeOTAD/Au	0.222	24.16	33	1.76	[ <mark>9</mark> 1]
One-step	$FASnI_3 + 20\% SnF_2$	c-TiO <sub>2</sub> /m-TiO <sub>2</sub> /perovskite/ spiro-MeOTAD/Au	0.238	24.45	36	2.10	[ <mark>99</mark> ]
One-step	$CsSnBr_3 + 20\% SnF_2$	c-TiO <sub>2</sub> /m-TiO <sub>2</sub> /perovskite/ spiro-MeOTAD/Au	0.42	9.1	57	2.17	[ <mark>89</mark> ]
One-step	MASnIBr <sub>2</sub>	c-TiO <sub>2</sub> /m-TiO <sub>2</sub> /perovskite/ spiro-MeOTAD/Au	0.69	15.9	49	5.36	[134]
One-step	$\mathrm{MASnI}_3 + 20\%~\mathrm{SnF}_2$	c-TiO <sub>2</sub> /m-TiO <sub>2</sub> /perovskite/ PTAA/Au	0.25	26.1	30	1.94	[137]
One-step	$\{en\}FASnI_3 + 15\% SnF_2$	c-TiO <sub>2</sub> /m-TiO <sub>2</sub> /perovskite/ PTAA/Au	0.48	22.54	65.96	7.14	[81]
One-step	$\{en\}FASnI_3 + 15\% SnF_2$	c-TiO <sub>2</sub> /m-TiO <sub>2</sub> /perovskite/ PTAA/Au	0.46	22.54	69.74	7.23	[138]
One-step	$\{PN\}FASnI_3 + 15\% SnF_2$	c-TiO <sub>2</sub> /m-TiO <sub>2</sub> /perovskite/ TPE/Au	0.44	22.15	60.67	5.85	[109]
One-step	$\{\mathrm{TN}\}\mathrm{FASnI}_3 + 15\%~\mathrm{SnF}_2$	c-TiO <sub>2</sub> /m-TiO <sub>2</sub> /perovskite/ PTAA/Au	0.40	22.72	61.04	5.53	[109]
One-step	$\{en\}MASnI_3 + 15\% SnF_2$	c-TiO <sub>2</sub> /m-TiO <sub>2</sub> /perovskite/ PTAA/Au	0.43	24.28	63.72	6.63	[108]
One-step	MASnBr <sub>3</sub>	c-TiO <sub>2</sub> /m-TiO <sub>2</sub> /perovskite/ PTAA/Au	0.307	1.22	36.8	0.14	[139]
One-step	$CsSnI_3 + 20\% SnF_2$	c-TiO <sub>2</sub> /m-TiO <sub>2</sub> /perovskite/m- MTDATA/Au	0.24	22.70	37	2.02	[88]
One-step	MASnCl <sub>3</sub>	c-TiO <sub>2</sub> /perovskite/CuSCN/Ag	0.576	12.89	55	3.41	[140]
One-step	CsSnI <sub>3</sub>	NiO/perovskite/PCBM/Al	0.52	10.21	62.5	3.31	[141]
One-step	CsSnI <sub>3</sub>	c-TiO <sub>2</sub> /perovskite/spiro-MeO- TAD/Au	0.48	8.11	19.8	0.77	[141]
One-step	$\mathrm{HEA}_{0.4}\mathrm{FA}_{0.6}\mathrm{SnI}_3$	c-TiO <sub>2</sub> /m-TiO <sub>2</sub> /perovskite/ Al <sub>2</sub> O <sub>3</sub> /C	0.37	18.52	56.2	3.9	[118]
One-step	$GA_{0.2}FA_{0.78}SnI_3 + 1\% EDAI_2$	PEDOT:PSS/perovskite/C <sub>60</sub> / BCP/Ag	0.61	21.2	72	9.6	[119]

 Table 1 (continued)

Preparation process	Absorber	Device architecture	$V_{\rm oc}$ (V)	$J_{\rm sc}~({\rm mA~cm^{-2}})$	FF (%)	PCE (%)	References
One-step	FASnI <sub>3</sub>	PEDOT:PSS/perovskite/ PCBM/BCP/Ag	0.49	22.24	65.19	7.15	[101]
One-step	FASnI <sub>3</sub>	SnO <sub>2</sub> /perovskite/PCBM/BCP/ Ag	0.55	19.39	68.82	7.34	[102]
One-step	FASnI <sub>3</sub>	PEDOT:PSS/perovskite/C <sub>60</sub> / BCP/Ag	0.63	21.6	74.7	10.17	[103]
One-step	FASnI <sub>3</sub>	PEDOT:PSS/perovskite/C <sub>60</sub> / BCP/Ag	0.628	22.25	74.2	10.37	[104]
One-step	$PEA_xFA_{1-x}SnI_3 + NH_4SCN$	PEDOT:PSS/perovskite/ ICBA/BCP/Ag	0.94	17.4	75	12.4	[135]
One-step	FASnI <sub>3</sub> +5% PHCl	PEDOT:PSS/perovskite/C <sub>60</sub> / BCP/Ag	0.76	23.5	64	11.4	[136]
Hot-casting	$BA_{2}MA_{3}Sn_{4}I_{13} + 100\% \ SnF_{2}$	c-TiO <sub>2</sub> /m-TiO <sub>2</sub> /perovskite/ PTAA/Au	0.229	24.1	45.7	2.53	[120]
Hot-casting	$MASnI_3 + 20\% SnF_2/hydrazine$	c-TiO <sub>2</sub> /m-TiO <sub>2</sub> /perovskite/ PTAA/Au	0.378	19.92	51.73	3.89	[142]
Hot-casting	$CsSnI_3 + 20\% SnF_2$ /hydrazine	c-TiO <sub>2</sub> /m-TiO <sub>2</sub> /perovskite/ PTAA/Au	0.170	30.75	34.88	1.83	[142]
Hot-casting	$CsSnBr_3 + 20\% SnF_2$	c-TiO <sub>2</sub> /m-TiO <sub>2</sub> /perovskite/ PTAA/Au	0.367	13.96	59.36	3.04	[142]
Hot-casting	MASnI <sub>3</sub>	PEDOT/perovskite/PCBM/Al	0.595	17.8	29.8	3.2	[143]
Vapor-assisted	MASnI <sub>3</sub>	c-TiO <sub>2</sub> /m-TiO <sub>2</sub> /perovskite/ PTAA/Au	0.273	17.36	39.1	1.86	[143]
Vapor-assisted	$MASnI_{3-x}Br_x$	c-TiO <sub>2</sub> /m-TiO <sub>2</sub> /perovskite/ PTAA/Au	0.452	5.02	48.3	1.10	[139]
Solvent-engineering	$FASnI_3 + 10\% SnF_2 + pyrazine$	c-TiO <sub>2</sub> /m-TiO <sub>2</sub> /perovskite/ spiro-MeOTAD/Au	0.32	23.7	63	4.8	[71]
Solvent-engineering	$FASnI_3 + 20\% SnF_2$	c-TiO <sub>2</sub> /m-TiO <sub>2</sub> /perovskite/ spiro-MeOTAD/Au	0.38	23.09	60.01	5.27	[97]
Solvent-engineering	$MASnI_3 + 20\% \ SnF_2$	c-TiO <sub>2</sub> /m-TiO <sub>2</sub> /perovskite/ spiro-MeOTAD/Au	0.232	26.0	38.6	2.33	[134]
Solvent-engineering	$\mathrm{FASnI}_3 + 10\% \ \mathrm{SnF}_2$	PEDOT:PSS/perovskite/C <sub>60</sub> / BCP/Ag	0.47	22.07	60.67	6.22	[96]
Solvent-engineering	$\begin{array}{c} \mathrm{FASnI}_3 + 20\% \; \mathrm{PEAI} + 10\% \\ \mathrm{SnF}_2 \end{array}$	NiO/perovskite/PCBM/Al	0.59	14.44	69	5.94	[127]
Solvent-engineering	$(FA)_{0.75}(MA)_{0.25}SnI_3 + 10\%$ SnF <sub>2</sub>	PEDOT:PSS/perovskite/C <sub>60</sub> / BCP/Ag	0.61	21.2	62.7	8.12	[80]
Solvent-engineering	$(FA)_{0.5}(MA)_{0.5}SnI_3 + 10\%$ SnF <sub>2</sub>	PEDOT:PSS/perovskite/C <sub>60</sub> / BCP/Ag	0.53	21.3	52.4	5.92	[80]
Solvent-engineering	$(FA)_{0.25}(MA)_{0.75}SnI_3 + 10\%$ SnF <sub>2</sub>	PEDOT:PSS/perovskite/C <sub>60</sub> / BCP/Ag	0.48	20.7	45.2	4.49	[80]
Solvent-engineering	$FASnI_3 + 10\% SnF_2$	PEDOT:PSS/perovskite/C <sub>60</sub> / BCP/Ag	0.48	21.3	64.6	6.60	[80]
Solvent-engineering	$\mathrm{MASnI}_3 \! + \! 10\% \; \mathrm{SnF}_2$	PEDOT:PSS/perovskite/C <sub>60</sub> / BCP/Ag	0.46	21.4	42.7	4.29	[80]
Solvent-engineering	$\begin{array}{c} 0.92 \mathrm{FASnI}_3 + 0.08 \mathrm{PEAI} + 10\% \\ \mathrm{SnF}_2 \end{array}$	-	0.525	24.1	71	9.0	[144]
Solvent-engineering	FASnI <sub>2</sub> Br	PEDOT:PSS/perovskite/C <sub>60</sub> / Ca/Al	0.467	6.82	54	1.72	[89]
Solvent-engineering	$MA_{0.9}Cs_{0.1}SnI_3$	PEDOT:PSS/perovskite/ PCBM/Bis-C <sub>60</sub> /Ag	0.20	4.53	36.4	0.33	[114]
Solvent-engineering	$FA_{0.8}Cs_{0.2}SnI_3$	PEDOT:PSS/perovskite/ PCBM/Bis-C <sub>60</sub> /Ag	0.24	16.05	35.8	1.38	[114]

Table 1	(continued)
Table I	(continucu)

Preparation process	Absorber	Device architecture	$V_{\rm oc}\left({\rm V}\right)$	$J_{\rm sc}~({\rm mA~cm^{-2}})$	FF (%)	PCE (%)	References
Solvent-engineering	FASnI <sub>3</sub>	PEDOT:PSS/perovskite/ PCBM/Bis-C <sub>60</sub> /Ag	0.04	11.73	23.4	0.11	[114]
Solvent-engineering	PEA <sub>2</sub> SnI <sub>4</sub>	NiO <sub>x</sub> /perovskite/PCBM/BCP/ Ag	0.61	22.0	70.1	9.41	[123]
Solvent-engineering	$(BA_{0.5}PEA_{0.5})_2FA_3Sn_4I_{13}\\$	PEDOT:PSS/perovskite/C <sub>60</sub> / LiF/Al	0.60	21.82	66.73	8.82	[126]
Solvent-engineering	$AVA_2FA_{n-1}Sn_nI_{3n+1}$	PEDOT:PSS/perovskite/ PCBM/BCP/Ag	0.61	21.0	68	8.71	[128]
Solvent-engineering	$(4AMP)(FA)_3Sn_4I_{13}$	c-TiO <sub>2</sub> /ZrO <sub>2</sub> /perovskite/C	0.64	14.9	44.3	4.42	[131]
Quantum rods	CsSnI <sub>3</sub>	c-TiO <sub>2</sub> /perovskite/spiro-MeO- TAD/Au	0.86	23.2	65	12.96	[145]
Quantum rods	CsSnBr <sub>3</sub>	c-TiO <sub>2</sub> /perovskite/spiro-MeO- TAD/Au	0.85	21.23	58	10.46	[145]
Quantum rods	CsSnCl <sub>3</sub>	c-TiO <sub>2</sub> /perovskite/spiro-MeO- TAD/Au	0.87	19.82	56	9.66	[145]
Sequential deposition	$FASnI_3 + 10\% SnF_2 + TMA$	SnO <sub>2</sub> /C <sub>60</sub> /perovskite/spiro- MeOTAD/Ag	0.31	21.65	64.7	4.34	[83]
Sequential deposition	$FASnI_3 + 10\% SnF_2 + TMA$	PEDOT:PSS/perovskite/C <sub>60</sub> / Bis-C <sub>60</sub> /Ag	0.47	22.45	0.68	7.09	[83]
Sequential deposition	FASnI <sub>3</sub>	PEDOT:PSS/perovskite/C <sub>60</sub> / BCP/Ag	0.33	17.78	67.9	3.98	[146]
Thermal evaporation	MASnBr <sub>3</sub>	c-TiO <sub>2</sub> /perovskite/P3HT/Au	0.498	4.27	49.1	1.12	[77]
Thermal evaporation	$CsSnBr_3 + 2.5\% SnF_2$	MoO <sub>3</sub> /perovskite/C <sub>60</sub> /BCP/Ag	0.40	2.4	55	0.55	[147]
Thermal evaporation	(PEA, FA) SnI <sub>3</sub>	LiF/PEDOT:PSS/perovskite/ C <sub>60</sub> /BCP/Ag	0.47	20.07	74	6.98	[148]
Thermal evaporation	MASnI <sub>3</sub>	PEDOT:PSS/TPD/perovskite/ C <sub>60</sub> /BCP/Ag	0.377	12.1	36.6	1.7	[149]
Thermal evaporation	CsSnI <sub>3</sub>	ITO/perovskite/Au/Ti	0.42	4.80	22	0.88	[87]
Direct dropping	$\mathrm{MASnIBr}_{1.8}\mathrm{Cl}_{0.2} + 20\%~\mathrm{SnF}_2$	c-TiO <sub>2</sub> /m-TiO <sub>2</sub> /m-Al <sub>2</sub> O <sub>3</sub> / perovskite/C	0.38	13.99	57.3	3.11	[150]
Hot-dropping	$CsSnIBr_2 + 60\% SnF_2 + H_3PO_2$	c-TiO <sub>2</sub> /m-TiO <sub>2</sub> /m-Al <sub>2</sub> O <sub>3</sub> / perovskite/C	0.31	17.4	56	3.2	[151]
Solvent-engineering	$\mathrm{FASnI}_3 + \mathrm{PEABr} + 10\% \ \mathrm{SnF}_2$	PEDOT:PSS/perovskite/C <sub>60</sub> / BCP/Cu	0.45	24.87	63	7.05	[152]
Solvent-engineering	$\frac{\text{FASnI}_{3} + 2.5\% \text{ N}_{2}\text{H}_{5}\text{Cl} + 10\%}{\text{SnF}_{2}}$	PEDOT:PSS/perovskite/ PCBM/BCP/Ag	0.455	17.64	67.3	5.40	[153]
Solvent-engineering	$FASnI_3 + 12\% SnF_2$	PEDOT:PSS(PEG)/perovskite/ PCBM/BCP/Ag	0.455	17.64	67.3	5.40	[153]
Solvent-engineering	$\mathrm{MASnI}_3 \! + \! 20\% \; \mathrm{SnF}_2$	PEDOT:PSS/perovskite/C <sub>60</sub> / BCP/Ag	0.45	11.82	40	2.14	[154]
Solvent-engineering	$FASnI_3 + 1\% EDAI_2$	PEDOT:PSS/perovskite/C <sub>60</sub> / BCP/Ag	0.583	21.3	0.72	8.9	[155]
Solvent-engineering	FASnI <sub>3</sub>	PEDOT:PSS/perovskite/C <sub>60</sub> / BCP/Ag	0.638	21.95	0.725	10.16	[156]

quality and reduced defect density, and the final device showed a PCE of 7.3% [102]. More importantly, about 50% of their original PCE was maintained after the 500 h storage in air. Soon after, Han et al. employed a  $\pi$ -conjugated Lewis base molecule 2-cyano-3-[5-[4-(diphenylamino) phenyl]-2-thienyl]-propenoic acid (CDTA) with high electron density to systematically control the crystallization rate of FASnI<sub>3</sub> perovskite [103]. They obtained a compact and uniform perovskite film with greatly increased carrier lifetime via forming stable intermediate phase with the Sn-I frameworks. Meanwhile, the introduction of the  $\pi$ -conjugated system also retarded the permeation of moisture into perovskite crystal, which significantly suppressed the film degradation in air [103]. The perovskite solar cell prepared on this basis achieved a PCE of 10.1% and maintained over 90% of its initial value after 1000 h light soaking in air. Another work is Han et al. introduced a liquid formic acid as a reducing solvent in the FASnI<sub>3</sub> perovskite precursor solution to product the FASnI<sub>3</sub> perovskite film with high crystallinity, low Sn<sup>4+</sup> content, reduced background doping, and low electronic trap density. As a result, the lead-free tin halide PSC achieved 10.37% efficiency [104].

In addition to additives, the use of antisolvents also greatly promoted the film quality of FASnI<sub>3</sub> perovskites. Typical antisolvents include chlorobenzene (CB) [105], toluene (TL) [106], diethyl ether (DE) [107], and other aprotic nonpolar solvents. Here, it is noteworthy that the antisolvents should be miscible with DMSO solvent, but insoluble for perovskites. Liao et al. used such a solvent-engineering method to fabricate FASnI<sub>3</sub> perovskites and tuned the film morphologies with different antisolvents (Fig. 3e-h) [96]. They obtained high-quality, uniform and fully covered FASnI<sub>3</sub> perovskite thin films. Among these antisolvents, dripping with diethyl ether onto FASnI<sub>3</sub> produced the best FASnI<sub>3</sub> thin films with high uniformity and full coverage. With improved film quality and proper structure design, the champion FASnI<sub>3</sub> device achieved a PCE of 6.22% with  $V_{\rm oc}$  of 0.465 V,  $J_{\rm sc}$  of 22.07 mA cm<sup>-2</sup>, and FF of 60.67%. Furthermore, such device exhibited a weak J-V hysteresis behavior [96].

Recently, a new type of "hollow" perovskites has been prepared. Chen et al. reported a successful incorporation of medium size cations ethylenediammonium (en) into the  $3D FASnI_3$  perovskite structure and they denoted it as  $\{en\}$ FASnI<sub>3</sub> [91, 108]. Typically, change of A-site cation only results in a small bandgap alteration due to structural distortion, but for  $\{en\}FASnI_3$ , its bandgap can be tuned in a wide range of 1.3–1.9 eV via simply increasing the en amount [108]. Actually, adding en could improve film morphology, reduce background carrier density and increase carrier lifetime, all of which contribute to the resultant PCE and stability of Sn-based solar cells [70]. Based on this viewpoint, the {en}FASnI<sub>3</sub> device achieved a 7.14% PCE with higher  $V_{\rm oc}$  and FF. Similar results were also observed in MASnI<sub>3</sub> and CsSnI<sub>3</sub> solar cells [108]. Recently, Kanatzidis et al. also reported two other diammonium cations of propylenediammonium (PN) and trimethylenediammonium (TN) forming new hollow perovskites of {TN}FASnI<sub>3</sub> and {PN}FASnI<sub>3</sub> [109]. TN and PN with slightly larger size than en also improved device performances. The FASnI<sub>3</sub> absorbers mixed with 10% PN and 10% TN achieved enhanced PCEs of 5.85% and 5.53%, respectively [109].

#### (4) Mixed A Cations Sn-Based Perovskites

Metal halide perovskites with mixed cations have been widely used in Pb-based PSCs, part of which achieved record efficiencies and good stability due to cation mixturetriggered film morphology improvement and water and oxygen resistance increase as well as inhibition of carrier recombination within devices [20, 22, 110–113]. In this case, it is also a powerful strategy to develop highly efficient, stable Sn-based PSCs with mixed A cations perovskites. Liu et al. first synthesized Sn-based perovskites with mixed cations of MA and Cs and applied MA<sub>0.9</sub>Cs<sub>0.1</sub>SnI<sub>3</sub> to PSCs [114]. The PCE was low (0.33%) since the device was fabricated without any optimization. Later, Zhao et al. reported 3D Sn-based perovskites with mixed cations of MA and FA (Fig. 6d). Notably, the optical property exhibited an obvious alteration with the ratio of mixed cations (Fig. 6a-c, e-f). Among them, (FA)<sub>0.75</sub>(MA)<sub>0.25</sub>SnI<sub>3</sub> perovskite solar cell with 10 mol % SnF<sub>2</sub> generated a maximum PCE of 8.12% and an average value of  $7.48\% \pm 0.52\%$  [88].

3.1.1.2 Low-Dimensional Sn-Based Perovskite As an alternative, reduced-dimensional (quasi-2D) perovskites have been widely investigated recently since they have showed superior enduring stability outperforming their 3D counterparts [115–117]. The existence of insulating organic spacer cations, e.g., PN [89], 2-hydroxyethylammonium (HEA) [118], guanidinium (GA) [119], butylammonium (BA) [120], polyethylenimine cation [121], cyclopropylammonium [122], and phenylethylammonium (PEA) on quasi-2D perovskites, restrains self-doping effect and suppresses ion migration [115, 121], thus contributing to ameliorated moisture, oxygen, and thermal stability. However, the emergence of these insulating long-chain organic cations also leads to the anisotropy characteristics of the crystal, which significantly reduces device performance. That means the resulting quasi-2D PSCs with enhanced stability are at the expense of declining performance due to blocked charge transportation of these insulating organic spacers along vertical direction [95, 120, 123]. The highly vertically oriented perovskite films are considered as a prerequisite to address

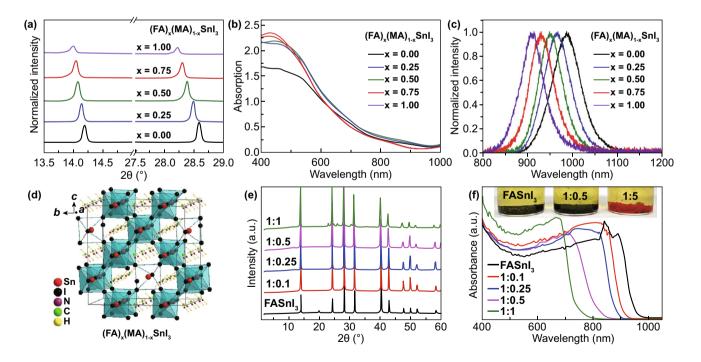
the low-efficiency issue in quasi-2D PSCs since in this situation these inorganic slabs are aligned in perpendicular to the substrates [124, 125]. Various methods of forming highly vertically oriented films have been developed in Pb-based quasi-2D perovskites, but unfortunately, most of which are unsuitable for Sn-based counterparts due to different properties between Pb- and Sn-based perovskites [123, 124]. In the published cases of Sn-based PSCs, Kanatzidis et al. reported 2D Ruddlesden-Popper (RP) perovskites  $(CH_3(CH_2)_3NH_3)_2(CH_3NH_3)_{n-1}Sn_nI_{3n+1}$  with perpendicular orientation by using N,N-dimethylformamide as solvent [120]. For n=4, perpendicularly oriented 2D perovskites were fabricated whether the substrates were heated or not, while for n=3, only hot substrates of 120 centigrade were able to intensify perpendicular growth of 2D films. Huang et al. introduced mixed *n*-butylamine and PEA organic cations into 2D RP Sn perovskite to control the crystallization process and formed highly vertically oriented [(BA <sub>0.5</sub>PEA<sub>0.5</sub>)<sub>2</sub>FA<sub>3</sub>Sn<sub>4</sub>I<sub>13</sub>] 2D RP perovskites [126]. Benefitting from it, the PCE of the 2D Sn-based PSC was improved to 8.82%. Liao et al. reported low-dimensional Sn-based perovskites by using FA and PEA mixed cations (Fig. 7a),

and they adjusted the orientation of the perovskite domains

by altering the PEA/FA ratios [127]. A highly oriented per-

ovskite film perpendicular to the substrate was realized by adding 20% PEA. As a result, the FASnI<sub>3</sub> perovskite solar cells with 20% PEA achieved a maximum PCE of 5.94% with enhanced stability [127]. Recently, Yuan et al. used the bifunctional cation 5-ammoniumvaleric acid (5-AVA) as the spacer to fabricate AVA<sub>2</sub>FA<sub>n-1</sub>Sn<sub>n</sub>I<sub>3n+1</sub> ( $\langle n \rangle = 5$ ) quasi-2D Sn-based perovskite, and by introducing appropriate amount of ammonium chloride (NH<sub>4</sub>Cl) additive, they obtained highly vertically oriented quasi-2D perovskite films which eventually enhanced the transportation of charge carriers between electrodes [128]. Actually, the Cl doping can also improve the electrical conductivity of perovskite film, as demonstrated by Li et al. [129].

In recent work, Padture et al. first reported the synthesis and photovoltaic performance of low-dimensional Dion–Jacobson Sn(II)-based halide perovskites (4AMP) (FA)<sub>n–1</sub>Sn<sub>n</sub>I<sub>3n+1</sub>, but the PSC based on this perovskite only achieved an efficiency of 2.15% [130]. Compared with the Sn-based perovskite of the RP layered with a van der Waals gap between the adjacent unit cells, the unique structure of DJ layered Sn-based perovskites allows the inorganic stacks to be more uniform and closer, rendering better alignment and less displacement of perovskites [131]. Moreover, the



**Fig. 6 a** XRD patterns of one-step deposited  $(FA)_x(MA)_{1-x}SnI_3$  (x=0.00, 0.25, 0.50, 0.75, and 1.00) films on ITO/poly(3,4ethylenedioxythiophene)-poly(styrenesulfonate) (PEDOT:PSS) substrates. **b** Absorption spectra and **c** normalized PL spectra of the different perovskite films on quartz substrates. **d** A 2×2×2 supercell of  $(FA)_2Sn_2I_6$  depicting a model of the hollow perovskite with two SnI<sub>2</sub> vacancies [(FA)<sub>16</sub>Sn<sub>14</sub>I<sub>44</sub>]. **e** XRD patterns and **f** optical absorption of the {en}FASnI<sub>3</sub> perovskite crystals with various molar ratios of FA to {en}. Reproduced with permission from Ref. [88]

shortened interlayer distance might reduce the barrier of charge transfer, which will benefit the charge transport of derived quasi-2D perovskite devices. It is particularly worth mentioning that the growth of the DJ phase perovskite layer can be controlled by selecting different diammonium organic cations as the intermediate spacer layer so that the growth direction is perpendicular to the substrate, which facilitates the transfer and collection of charge through the electrode [124, 132]. These characteristics will make DJ Sn-based perovskites to be a promising class of materials for photovoltaic applications.

Kanatzidis et al. reported some hexagonal polytypes and low-dimensional structures of hybrid Sn iodide perovskites, which employed various small cations such as trimethylammonium (TMA<sup>+</sup>), imidazolium (IM<sup>+</sup>), guanidinium (GA<sup>+</sup>), ethylammonium (EA<sup>+</sup>), acetamidinium (ACA<sup>+</sup>), and isopropylamine (IPA<sup>+</sup>) (Fig. 7b–e) [133]. Due to the moderate size of these cations, a variety of new ASnX<sub>3</sub> polytypes were formed by combinations of corner-sharing octahedra (perovskite) and face-sharing octahedra (perovskitoid), which have the potential for lead-free solar cells [134]. Finally, we summarize the current research results of Sn-based perovskite solar cells in Table 1 [70, 71, 80–83, 87–89, 96, 97, 101–104, 118–120, 124, 133–156].

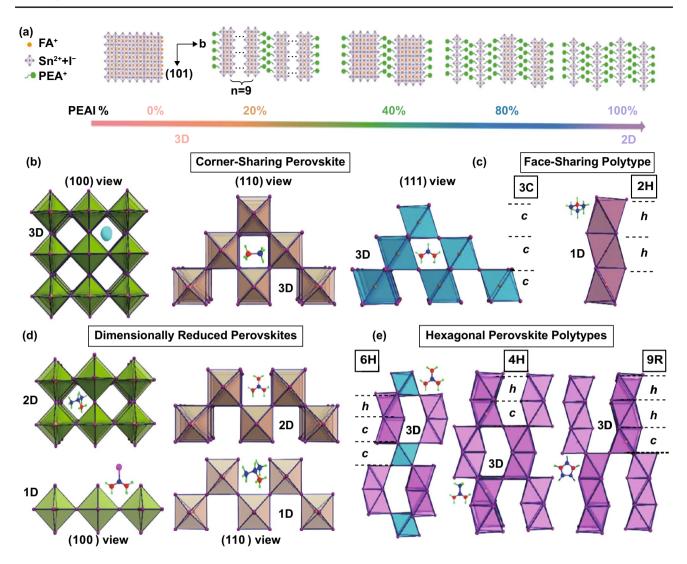
To further improve the efficiency of tin-based perovskite, device structure manipulation was also conducted by Ning et al., who used indene-C<sub>60</sub> bisadduct as the ETL to fabricate solar cells based on PEA<sub>x</sub>FA<sub>1-x</sub>SnI<sub>3</sub> perovskite, yielding a high efficiency of 12.4% [135]. In addition to efficiency, the stability issue of tin-based PSCs also restrained their applications. Mathews et al. encapsulated FASnI<sub>3</sub> PSCs and realized more stable PSCs with over 80% of its initial PCE being maintained after 1-month storage in a N<sub>2</sub> environment, which is much better than the unencapsulated counterparts that fully decomposed within two weeks [71]. In addition, Kanatzidis et al. studied the encapsulated 2D (BA)<sub>2</sub>(MA)<sub>3</sub>Sn4I<sub>13</sub> PSCs and their test results showed that the encapsulated device retained more than 90% of its initial performance after 1 month and dropped only to ~ 50% after 4 months in a glove box full of  $N_2$  [120]. This encouraging stability is closely related to the intrinsically stable 2D perovskite structure as well as the encapsulation that sufficiently blocked the invasion of water and oxygen. Other researchers have also proposed in their respective work that it is possible to package Sn-based solar cells to improve stability [71, 103, 104, 120, 136, 155, 156].

In summary, there is still a large room for efficiency and stability enhancements of Sn-based perovskites. Future works should focus on optimization of perovskite composition and selection of effective additives to fabricate stable and high-quality perovskite film with less  $Sn^{2+}$  oxidation. Besides, reasonable choice of hole/electron transport materials is very critical for enhancing device performance and stability of the Sn-based PSCs. Protecting of solar cells with industrial encapsulation techniques will also be a viable approach to improve the long-term stability of the Sn-based PSCs and push it to the commercial market.

#### 3.1.2 Ge-based Perovskite

Previous reports have shown that metal ions owning external  $ns^2$  electronic structure with low ionization energy can enhance light absorption efficiency and carrier diffusion length of ABX<sub>3</sub> structure. Ge<sup>2+</sup> has similar outer ns<sup>2</sup> electronic structure (4s<sup>2</sup>) to Sn<sup>2+</sup> (5s<sup>2</sup>) and Pb<sup>2+</sup> (6s<sup>2</sup>), but smaller ionic radii than Sn<sup>2+</sup> and Pb<sup>2+</sup> [64]. Ge-based perovskites containing MAGeI<sub>3</sub>, CsGeI<sub>3</sub> and FAGeI<sub>3</sub> have also been demonstrated to be stable at temperature of up to 150 °C. According to these data, Mathews et al. considered that Ge could replace Pb as a new type of lead-free perovskite material [64]. Actually, the bandgaps of the Ge-based perovskites can be adjusted close to the conventional lead halide perovskite of 1.5 eV via altering A-site cations.

Kanatzidis et al. synthesized a series of AGeI<sub>2</sub> perovskite compounds and characterized their structural, electronic and optical properties in 2015 [61]. The bandgaps of the Ge-based perovskites increase with the increased radius of the A cation. For instance, CsGeI<sub>3</sub> has an optical bandgap of 1.63 eV, whereas other AGeI<sub>3</sub> perovskites universally exhibit wide bandgap values of  $\geq 2.0$  eV. These AGeI<sub>3</sub> perovskites are rhombohedral crystal structures at room temperature [60]. Kanatzidis et al. [61] used the pyramidal [GeI<sub>3</sub>]<sup>-</sup> building block to synthesize a series of Ge-based perovskites and adjusted their A-site cations. The experimental results showed that CsGeI<sub>3</sub>, MAGeI<sub>3</sub>, FAGeI<sub>3</sub> and CH<sub>3</sub>C(NH<sub>2</sub>)<sub>2</sub>GeI<sub>3</sub> were 3D perovskite structures with direct bandgaps of 1.6, 1.9, 2.2, and 2.5 eV, respectively, while C(NH<sub>2</sub>)<sub>3</sub>GeI<sub>3</sub>, (CH<sub>3</sub>)<sub>2</sub>C(H)NH<sub>3</sub>GeI<sub>3</sub>, and (CH<sub>3</sub>)<sub>3</sub>NHGeI<sub>3</sub> were 1D infinite chain structures separately with indirect bandgaps of 2.7, 2.5, and 2.8 eV, among which CsGeI<sub>3</sub> exhibited the highest optical absorption coefficient (Fig. 8a) and showed much more application potential in photovoltaic field.



**Fig. 7** a Schematic structures of mixed FA/PEA Sn perovskites with PEAI/FAI doping ratios of 0, 20, 40, 60, 80, and 100%. Reproduced with permission from Ref. [127]. b Three alternative views of the archetypal 3D perovskite structure viewed along the (100), (110), and (111) cleavage planes. c "Perovskitoid" face-sharing building block of the 1D structures obtained for t > 1 representing the archetypal hexagonal polytype. d Perovskite structures obtained through dimensional reduction featuring corner-sharing 2D sheets and 1D chains through the (100) and (110) cleavage planes, respectively. e Hexagonal perovskite polytypes obtained from a linear combination of the corner-sharing 3D perovskite along the (111) cleavage plane and the 1D face-sharing polytype. The "h" and "c" symbols indicate hexagonal and cubic layers, respectively, and serve in identifying the layer sequence that characterizes the polytype. Reproduced with permission from Ref. [135]

The photoluminescence (PL) measurements of CsGeI<sub>3</sub> single crystals exhibited two peaks at 0.82 µm (1.51 eV) and 1.15 µm (1.08 eV), which were respectively assigned to the interband transition at  $\alpha$ . k=( $\pi$ /a) (111) and the energy band change (Fig. 9a). The energy bands of the Ge-based perovskites with different A cations are shown in Fig. 9b. Fourier transform infrared spectroscopy showed that the transparent range of CsGeI<sub>3</sub> can be extended from ~2 to > 12 µm. The short-wave cutoff is mainly limited by the energy band, and

the longest infrared transparency wavelength may originate from the phonon absorption of crystal lattice, and a specific rhombohedral crystal structure can be generated at room temperature [157]. Mathews et al. used hypophosphorous acid to improve the solubility of Ge perovskite precursor in organic solvent and prepared Ge-based perovskite films [60]. According to the SEM images (Fig. 9d–f), the films of MAGeI<sub>3</sub> and CsGeI<sub>3</sub> exhibited nearly full-coverage morphology, but the FAGeI<sub>3</sub> film showed a poor quality. Based on these films, they then fabricated devices on mesoporous  $TiO_2$  structures. MAGeI<sub>3</sub> and CsGeI<sub>3</sub> solar cells showed  $J_{sc}s$  of 4.0 and 5.7 mA cm<sup>-2</sup> and PCEs of 0.11 and 0.2%, respectively, as shown in Fig. 9c. In contrast, FAGeI<sub>3</sub> solar cell with poor film morphology displayed no photocurrent.

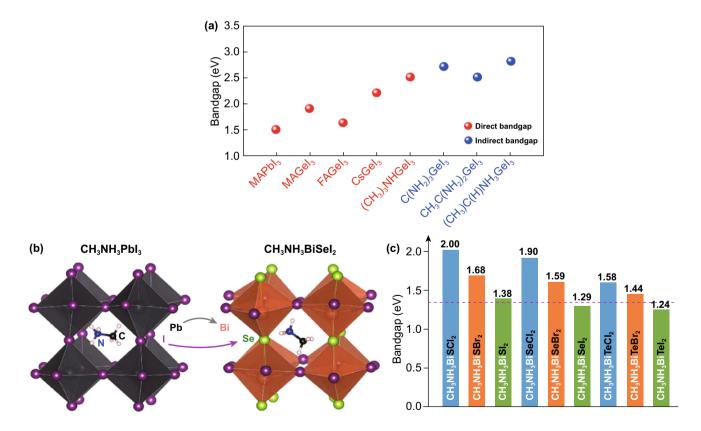
Kopacic et al. [158] demonstrated that chemical composition engineering of MAGeI<sub>3</sub> significantly improved performances of solar cells and simultaneously enhanced their stability. By introducing bromide anion to partially replace idiode, the PCE based on MAGeI<sub>2.7</sub>Br<sub>0.3</sub> was increased up to 0.57%.

Generally, Ge-based perovskites exhibit obviously different energy structures from the Pb-based ones and thus suitable ETL and HTL should be optimized to improve charge extraction efficiency in the device. More importantly, stabilization of  $Ge^{2+}$  in Ge-based perovskite is also a pretty challenging task to be solved. Otherwise, the stability issue and extremely low PCE will limit broader photovoltaic applications of this kind of perovskites.

#### 3.1.3 Transition Metal Halide Perovskite

Divalent transition metal cations (e.g.,  $Cu^{2+}$ ,  $Fe^{2+}$ ,  $Zn^{2+}$ ) have also been considered as the candidates of Pb-free perovskites, which can be synthesized via a variety of routes to tune photovoltaic properties [63, 159]. Because of small ionic radii for transition metal ions (e.g., 0.73 nm for Cu(II) and 0.78 nm for Fe(II)) that far deviated from tolerance factor of 1, 3D structure (e.g.,  $K_2NiF_4$ ) cannot be maintained and it turns into stable 2D layered structure along < 100 > , < 110 > and < 111 > orientations [160].

 $Cu^{2+}$  is a promising Pb-free perovskite in consideration of its good stability, earth abundance, low-cost and sufficient absorption in near-infrared region. Currently, some Cu-based perovskites have been developed for solar cell applications [63, 161, 162]. Cortecchia et al. first used the 2D crystal structure of MA<sub>2</sub>CuCl<sub>x</sub>Br<sub>4-x</sub> (Fig. 10a) as a light absorbing layer to fabricate solar cell [63]. They mixed MABr, MACl, CuCl<sub>2</sub> and CuBr<sub>2</sub> in DMSO as the precursor



**Fig. 8** a Bandgaps of various Ge-based perovskite materials compared with MAPbI<sub>3</sub>. **b** Atomic structures of MAPbI<sub>3</sub> and MABiSeI<sub>2</sub>. **c** Calculated bandgaps of  $CH_3NH_3BiXY_2$  compounds (with X = S, Se, Te and Y = Cl, Br, or I) using the Heyd–Scuseria–Ernzerhof functional with spin–orbit coupling. The dashed line marks the optimal bandgap for single-junction solar cell according to the Shockley–Queisser theory. Reproduced with permission from Ref. [52]

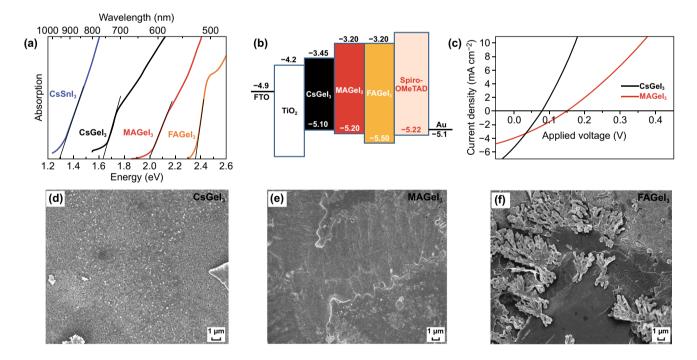
solution and tuned the bandgaps of  $MA_2CuCl_{v}Br_{4-v}$  from 2.48 to 1.80 eV via changing the Br content (Fig. 10b). Cubased perovskites exhibited a narrow bandgap with low conduction band compared to other non-transition metal perovskite compounds, whose conduction band is derived from the unoccupied Cu 3d orbitals hybridized with Br/ Cl p orbitals. The MA<sub>2</sub>CuCl<sub>x</sub>Br<sub>4-x</sub> layer was fabricated on the FTO/mesoporous TiO<sub>2</sub> substrate by spin coating process. A PCE of 0.017% was obtained with extremely low  $J_{\rm sc}$  of 216  $\mu$ A cm<sup>-2</sup> and  $V_{\rm oc}$  of 0.256 V (Fig. 10c). In addition, they also prepared planar heterojunction cells based on MA<sub>2</sub>CuCl<sub>x</sub>Br<sub>4-x</sub>, but the PCE was far less than 0.017%. The higher PCE for mesoporous structure solar cell arises from improved charge extraction and vertical charge transport along with the destruction of the 2D structure of  $MA_2CuCl_xBr_{4-x}$  perovskite by mesoporous TiO<sub>2</sub>. The solar cells with  $MA_2CuCl_xBr_{4-x}$  as the light absorber showed better stability due to the essential role of Cl<sup>-</sup>, but unfortunately, the low absorption coefficient and heavymass hole limited their device performances. Subsequent works showed that  $(C_6H_5CH_2NH_3)_2CuBr_4$ ,  $(\rho-FC_6H_5C_2H_4 NH_3$ <sub>2</sub>CuBr<sub>4</sub> and (CH<sub>3</sub>(CH<sub>2</sub>)<sub>3</sub>NH<sub>3</sub>)<sub>2</sub>CuBr<sub>4</sub> based solar cells had slightly higher PCEs of 0.2%, 0.51%, and 0.63% [161, 162].

On the whole, Cu-based perovskites are relatively stable compared to other transition metal perovskite materials despite of the universially low conversion efficiency. How to reduce their wide optical bandgap and improve their charge transfer rate is the bottleneck problems limiting the further development of this type of perovskites. We believe that Cu-based perovskites will be an important part of lead-free perovskite solar cells once overcoming these problems.

#### 3.2 Lead Replacement by Heterovalent Elements

#### 3.2.1 $A_3B_2X_9$ Perovskite

Bi-based perovskites represent a successful example in lead-free perovskite materials family with low toxicity, air stability, and a fair degree of tunability. Abulikemu et al. successfully fabricated  $(CH_3NH_3)_3Bi_2I_9$  powders, millimeter-scale single crystals and thin films with solvent-based crystallization methods (Fig. 11a, b) [163]. Compared with Pb-based counterpart,  $(CH_3NH_3)_3Bi_2I_9$  perovskite has better



**Fig. 9** a Tauc plot for CsSnI<sub>3</sub>, CsGeI<sub>3</sub>, MAGeI<sub>3</sub>, and FAGeI<sub>3</sub> showing optical bandgaps of 1.29, 1.63, 2.0, and 2.35 eV, respectively. b Energy level pattern for the PSCs with CsGeI<sub>3</sub>, MAGeI<sub>3</sub>, and FAGeI<sub>3</sub> absorbers. c Comparison of J-V curves of CsGeI<sub>3</sub> and MAGeI<sub>3</sub> solar cells. d-f SEM images for CsGeI<sub>3</sub>, MAGeI<sub>3</sub>, and FAGeI<sub>3</sub> films both deposited on the compact TiO<sub>2</sub>/mesoporous TiO<sub>2</sub> substrates. Reproduced with permission from Ref. [60]

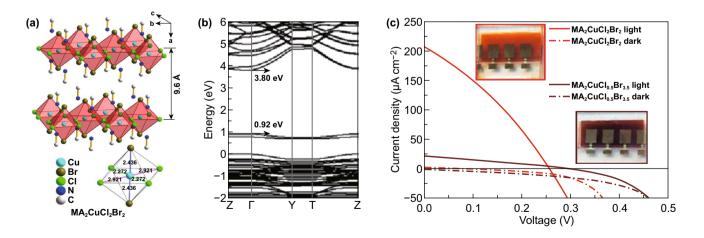
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stability. In response to the rapid crystallization of perovskites during film formation, the researchers proposed two thin film annealing methods to improve the film-forming quality. One was an antisolvent assisted crystallization route, which dropped antisolvent of chlorobenzene during the spin coating process of precursors and then annealed at 70 °C for 10 min to form perovskite film. The other method was denominated saturated vapor crystallization. The perovskite film was fabricated without dropping chlorobenzene during the spin coating process, and then annealed in a closed Petri dish at 60 °C overnight to slow the solvent evaporation, which generated a highly oriented single-crystal film (Fig. 11b, c). Solar cell devices were fabricated based on these thin films, achieving an efficiency of 0.11%, an FF of 31.80%, an average  $J_{sc}$  of 491.89  $\mu$ A cm<sup>-2</sup> and a  $V_{oc}$  of 0.7216 V (Fig. 11d, e). However, the external quantum efficiency (EQE) spectrum demonstrated that the device produced photocurrent merely at a short wavelength, with most part of the visible spectrum missed (e.g., above 500 nm) [163]. The explanation given by the researchers was that the depletion of EQE in the (CH<sub>3</sub>NH<sub>3</sub>)<sub>3</sub>Bi<sub>2</sub>I<sub>0</sub> film was attributed to its inhomogeneity and discontinuity between crystallites in terms of high recombination of photogenerated charges, so the high-quality perovskite film is a prerequisite to achieve a high efficiency.

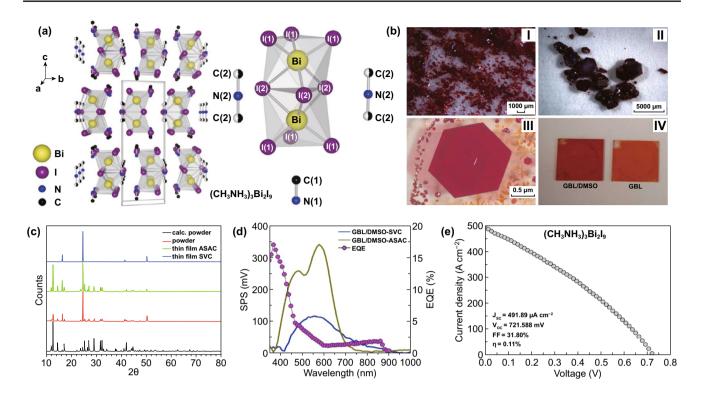
Buonassisi et al. used solution-processing and vaporassisted techniques to synthesize pure phase  $(CH_3NH_3)_3Bi_2I_9$ perovskite (Fig. 12a) [164]. They found that the crystal structure of the pure phase  $(CH_3NH_3)_3Bi_2I_9$  was composed of alternate MA<sup>+</sup> and  $\text{Bi}_2\text{I}_9^{3-}$  groups (Fig. 13b). The perovskite films prepared by this method were densely packed with high coverage and also showed excellent stability (Fig. 12c, d). The vapor processed films also got a longer PL decay time [164].

Very recently, Zhang et al. made a breakthrough in experimental method of fabricating high-quality (CH<sub>3</sub>NH<sub>3</sub>)<sub>3</sub>Bi<sub>2</sub>I<sub>9</sub> film [165]. They employed a novel solvent-free high-low vacuum deposition (HLVD) procedure to obtain smooth, compact and pinhole-free polygonal crystal (CH<sub>3</sub>NH<sub>3</sub>)<sub>3</sub>Bi<sub>2</sub>I<sub>0</sub> film and then fabricated heterojunction solar cells. The HLVD approach proposed here is a two-step alternate vacuum deposition of Bil<sub>3</sub> and MAI under high- and lowvacuum, which can be further transformed to the resultant  $(CH_3NH_3)_3Bi_2I_0$  perovskite. With the approximate 300 nm (CH<sub>3</sub>NH<sub>3</sub>)<sub>3</sub>Bi<sub>2</sub>I<sub>9</sub> film as the light absorption layer to construct the planar heterojunction PSCs, they not only achieved a high PCE of 1.64% and a high EQE close to 60%, but also obtained a good stability during the measurement of 15 weeks, demonstrating the potential of  $(CH_3NH_3)_3Bi_2I_9$ for highly efficient and stable solar cells.

In subsequent research, Ran et al. synthesized a smooth, uniform and pinhole-free  $(CH_3NH_3)_3Bi_2I_9$  thin film with a novel two-step evaporation spin coating film fabrication strategy (Fig. 13a, b) [166]. They further optimized film formation conditions by comparing the integrated current from the IPCE measurements and formed compact  $(CH_3NH_3)_3Bi_2I_9$  thin films. By taking advantage of the optimized compact thin film, they manufactured inverted



**Fig. 10** a Crystal structure of MA<sub>2</sub>CuCl<sub>2</sub>Br<sub>2</sub>, showing the alternation of organic and inorganic layers and the Cu-X bond lengths in the inorganic framework. **b** Electronic band structure of MA<sub>2</sub>CuClBr<sub>3</sub> investigated by DFT simulation. **c** J-V curve of solar cells sensitized with MA<sub>2</sub>CuCl<sub>2</sub>Br<sub>2</sub> (red) and MA<sub>2</sub>CuCl<sub>0.5</sub>Br<sub>3.5</sub> (brown) under 1 sun of light illumination. The red and brown dashed lines represent dark current. Reproduced with permission from Ref. [63]



**Fig. 11 a** A representation of the layered structure of  $(CH_3NH_3)_3Bi_2I_9$ , characterized by isolated  $[Bi_2I_9]^{3-}$  anions and two crystallographic inequivalent  $CH_3NH_3^+$  cations. **b** Small single-crystal powder grown from  $Bi_2O_3$  and  $CH_3NH_3I$  in concentrated HI (I–III). And  $(CH_3NH_3)_3Bi_2I_9$  thin films deposited by the antisolvent assisted crystallization method (ASAC) using GBL/DMSO and GBL as solvents and chlorobenzene as antisolvent (IV). **c** Diffraction patterns of  $(CH_3NH_3)_3Bi_2I_9$  thin films, powder and simulated powder from single-crystal XRD measurements. **d** EQE of a typical FTO/TiO<sub>2</sub>/( $CH_3NH_3$ )\_3 $Bi_2I_9$ /spiro-MeOTAD/Au device. **e** *J*–*V* scanning of the best-forming device. Reproduced with permission from Ref. [163]

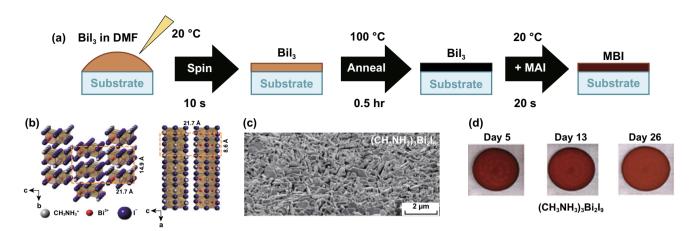
planar heterojunction photovoltaic device with a PCE of 0.39% and a high  $V_{oc}$  of 0.83 V, which exhibited the lowest loss-in-potential to date in  $(CH_3NH_3)_3Bi_2I_9$ -based solar cells (Fig. 13c–e). However, there still existed a slight hysteresis effect in the *J*–*V* curves [166]. This work certificates that the film morphology engineering is crucial for improving the optoelectronic performance of Bi-based hybrid perovskites solar cells.

Additionally, Park et al. confirmed more efficient solar cells with MA cations replaced by Cs cations in Bi-based perovskite [59]. On the basis of that research, Johansson et al. introduced a bismuth halide as the light absorber with the chemical composition of  $Cs_3Bi_2I_9$  in their solar cells [167]. The morphology of the  $Cs_3Bi_2I_9$  sample showed hexagonal flakes with size up to 2 µm, which were vertically organized and penetrated into TiO<sub>2</sub>. The TiO<sub>2</sub> can be seen in the gaps between the large flakes due to the unique perovskite morphology and stacking mode. The best-performing device based on  $Cs_3Bi_2I_9$  showed a  $J_{sc}$ 

2.2 mA cm<sup>-2</sup>, but lower  $V_{oc}$  and FF values generated a PCE of 0.4% [167].

Although researchers have got some successful examples of Bi-based perovskites, the performances of their perovskite solar cells are still universally low due to the intrinsic large bandgaps, large carrier effective masses, large exciton binding energies, more internal defects and defect intolerance. Design of new Bi-based lead-free perovskite materials avoiding above issues on the basis of theoretical calculation is critical for further development of high-performance solar cells. In addition, accurate control of formation rate with facile process technologies (e.g., moisture assisted growth, vacuum deposition, hot spin coating, and so forth) to improve the film quality of Bi-based perovskite allows for an improved performance of Bi-based lead-free perovskite devices. Here, we summarize the current research results of Bi-based PSCs in Table 2 [59, 161, 163–170].

Sb is in the same element group as Bi with low toxicity although it is a heavy metal [171, 172]. Halide perovskites



**Fig. 12** a Schematic diagram of  $(CH_3NH_3)_3Bi_2I_9$  solution-assisted process. **b** Crystal structure and (001) view of  $(CH_3NH_3)_3Bi_2I_9$ . **c** SEM image of  $(CH_3NH_3)_3Bi_2I_9$  thin film. **d** Stability measurement of  $(CH_3NH_3)_3Bi_2I_9$  in air. Reproduced with permission from Ref. [164]

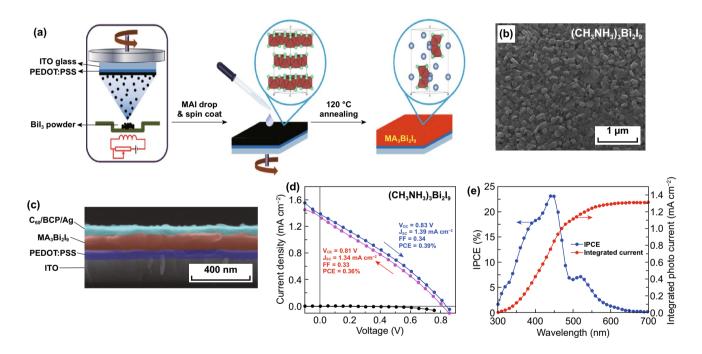


Fig. 13 a Fabrication procedure and b SEM image of  $(CH_3NH_3)_3Bi_2I_9$  film. c Cross-sectional SEM image of  $(CH_3NH_3)_3Bi_2I_9$ -based solar cells. d Forward and backward scanning and e IPCE spectra of the best-forming device. Reproduced with permission from Ref. [166]

based on group-VA cations of Sb<sup>3+</sup> are promising candidates due to the same lone-pair  $ns^2$  state as Pb<sup>2+</sup>. Through a joint experimental and theoretical study, researchers found that a 0D structure was formed in Sb-based perovskite, which was similar to Bi, but with lower exciton binding energies. Mitzi et al. reported a highly oriented Sb-based perovskite thin film by a two-step deposition approach. Large grain (> 1 µm) and continuous thin films of the lead-free perovskite Cs<sub>3</sub>Sb<sub>2</sub>I<sub>9</sub>

were achieved by annealing the evaporated CsI in SbI<sub>3</sub> vapor at 300 °C for 10 min, and the  $\langle 111 \rangle$ -stacked layered perovskite structure was convinced by the X-ray diffraction (XRD) patterns [62]. The layered inorganic Cs<sub>3</sub>Sb<sub>2</sub>I<sub>9</sub> has a bandgap of 2.05 eV, measured by ultraviolet photoelectron spectroscopy, inverse photoemission spectroscopy and X-ray photoelectron spectroscopy (XPS), which showed similar absorption as high as CH<sub>3</sub>NH<sub>3</sub>PbI<sub>3</sub>. The DFT calculations

indicated  $Cs_3Sb_2I_9$  has a nearly direct bandgap in consideration of less than 0.02 eV difference between the direct and indirect bandgaps. Then Mitzi et al. prepared PSCs with the  $Cs_3Sb_2I_9$  material, which produced a low PCE of less than < 1%, a significant hysteresis effect, and an enhanced air stability compared to  $CH_3NH_3PbI_3$  counterpart [62].

Kirchartz et al. presented solution-treated trivalent antimony perovskite  $(CH_3NH_3)_3Sb_2I_9$  and fabricated a planar heterojunction solar cell with this compound (Fig. 14a–c), yielding a PCE of ~0.5%, a decent FF of 55%, a  $V_{oc}$  of 0.89 V and a low photocurrent density of 1.0 mA cm<sup>-2</sup> [173]. They determined a peak absorption coefficient ( $\alpha$ ) of ~10<sup>5</sup> cm<sup>-1</sup> and an optical bandgap of 2.14 eV for amorphous (CH<sub>3</sub>NH<sub>3</sub>)<sub>3</sub>Sb<sub>2</sub>I<sub>9</sub> films by photothermal deflection spectroscopy. The PL was observed at 1.58 eV, and the Urbach tail energy of this amorphous composite was  $62 \times 10^{-3}$  eV, demonstrating a substantial amount of energetic disorder [173]. The wide optical bandgap and energetic disorder may be the source of low photocurrent densities. In a word, this type of 0D dimer-phase trivalent antimony perovskite suffers from intrinsic problems including a low-symmetry induced indirect bandgap, strong quantumconfinement effect caused oversized gap values, and inferior hopping-like carrier transport, thus it is unfavorable for photovoltaic applications with extremely low PCEs of less than 0.5% obtained [62, 173].

The 2D layered phase can partially circumvent the abovementioned problems and is expected to show a direct bandgap, smaller optical bandgap and good in-layer carrier transport properties. Recently, with the introduction of small-size  $Rb^+$  and  $NH_4^+$  as the A-site cations, 2D layered phases of  $Rb_3Sb_2I_9$  [174] and  $(NH_4)_3Sb_2I_9$  [175] have been realized using low-temperature solution processing. Zhou et al. performed comprehensive chemical composition engineering of the precursor solutions by incorporating MACl into the mixture of SbI<sub>3</sub> and MAI, and successfully realized a phase transformation from the 0D dimer phase to the 2D layered one [176]. As displayed in Fig. 14d-j, the presence of the 2D layered phase was demonstrated by X-ray diffraction measurements, optical absorbance spectroscopy, and direct comparison of the experimental data with theoretical calculations. With high-quality films of the 2D layered

Table 2 Photovoltaic parameters of PSCs based on various Bi-based perovskite absorbers

Preparation process	Absorber	Device architecture	$V_{\rm oc}\left({\rm V}\right)$	$J_{\rm sc}~({\rm mA~cm^{-2}})$	FF (%)	PCE (%)	References
One-step spin coating	Cs <sub>3</sub> Bi <sub>2</sub> I <sub>9</sub>	c-TiO <sub>2</sub> /m-TiO <sub>2</sub> /perovskite/ P3HT/Ag	0.31	0.34	38	0.40	[165]
One-step spin coating	(CH <sub>3</sub> NH <sub>3</sub> ) <sub>3</sub> Bi <sub>2</sub> I <sub>9</sub>	c-TiO <sub>2</sub> /perovskite/spiro/Au	0.72	0.49	31.8	0.11	[161]
One-step spin coating	$(CH_3NH_3)_3Bi_2I_9$	c-TiO <sub>2</sub> /m-TiO <sub>2</sub> /perovskite/ spiro-MeOTAD/Au	0.68	0.38	88	0.22	[166]
One-step spin coating	$(CH_3NH_3)_3Bi_2I_9$	c-TiO <sub>2</sub> /m-TiO <sub>2</sub> /perovskite/ spiro-MeOTAD/Ag	0.68	0.52	33	0.12	[59]
One-step spin coating	Cs <sub>3</sub> Bi <sub>2</sub> I <sub>9</sub>	c-TiO <sub>2</sub> /m-TiO <sub>2</sub> /perovskite/ spiro-MeOTAD/Ag	0.85	2.15	60	1.09	[59]
One-step spin coating	(CH <sub>3</sub> NH <sub>3</sub> ) <sub>3</sub> Bi <sub>2</sub> I <sub>9</sub> Cl <sub>x</sub>	c-TiO <sub>2</sub> /m-TiO <sub>2</sub> /perovskite/ spiro-MeOTAD/Ag	0.04	0.18	38	0.03	[59]
One-step spin coating	$(CH_3NH_3)_3Bi_2I_9$	c-TiO <sub>2</sub> /m-TiO <sub>2</sub> /perovskite/ P3HT/Au	0.35	1.157	46.4	0.19	[167]
One-step spin coating	(CH <sub>3</sub> NH <sub>3</sub> ) <sub>3</sub> Bi <sub>2</sub> I <sub>9</sub>	c-TiO <sub>2</sub> /m-TiO <sub>2</sub> /perovskite/ PIF8-TAA/Au	0.85	1.22	73	0.71	[168]
Two-step evaporation spin coating	(CH <sub>3</sub> NH <sub>3</sub> ) <sub>3</sub> Bi <sub>2</sub> I <sub>9</sub>	PEDOT:PSS/perovskite/C <sub>60</sub> / BCP/Ag	0.83	1.39	37	0.39	[164]
Two-step thermal evaporation	(CH <sub>3</sub> NH <sub>3</sub> ) <sub>3</sub> Bi <sub>2</sub> I <sub>9</sub>	c-TiO <sub>2</sub> /m-TiO <sub>2</sub> /perovskite/ spiro-MeOTAD/Au	0.83	3.00	79	1.64	[163]
Vapor-assisted solution process	(CH <sub>3</sub> NH <sub>3</sub> ) <sub>3</sub> Bi <sub>2</sub> I <sub>9</sub>	c-TiO <sub>2</sub> /m-TiO <sub>2</sub> /perovskite/ P3HT/Au	1.01	4.02	78	3.17	[169]
One-step spin coating	Cs <sub>3</sub> Bi <sub>2</sub> I <sub>9</sub>	c-TiO <sub>2</sub> /perovskite/spiro-MeO- TAD/Au	0.79	4.45	50.34	1.77	[170]
One-step spin coating	Cs <sub>3</sub> Bi <sub>2</sub> I <sub>9</sub>	c-TiO <sub>2</sub> /perovskite/CuI/Au	0.86	5.78	64.38	3.20	[170]
One-step spin coating	Cs <sub>3</sub> Bi <sub>2</sub> I <sub>9</sub>	c-TiO <sub>2</sub> /perovskite/PTAA/Au	0.83	4.82	57.49	2.30	[170]

 $MA_3Sb_2Cl_XI_{9-X}$  perovskites as light absorbers, they fabricated solar cells with PCEs of over 2% [176].

So far, the Sb-based perovskites, similar to bismuth ones, still show a limited efficiency. But they own a bright application prospect once their nearly direct bandgap can be adjusted to a suitable value (e.g., doping) that matches with solar spectra. In addition, Sb-based perovskites can form a more stable 2D layered phase, which are better for carrier transport and display improved optoelectronic properties compared with the 0D Bi-based counterparts.

#### 3.2.2 Chalcogen–Halogen Hybrid Perovskite

In 2015, Sun et al. proposed the anion-split approach based on first-principles calculation, where dual anions (e.g., halogen and chalcogen anions) were introduced while Pb was replaced by heterovalent non-toxic elements in order to keep the 3D perovskite structure and the charge neutrality (Fig. 8b, c) [52]. Figure 8b shows the atomic structure of MABiSeI<sub>2</sub>, which maintained the MAPbI<sub>3</sub> tetragonal structure with a freely rotating MA<sup>+</sup> ion according to ab initio molecular dynamics (AIMD) simulations.

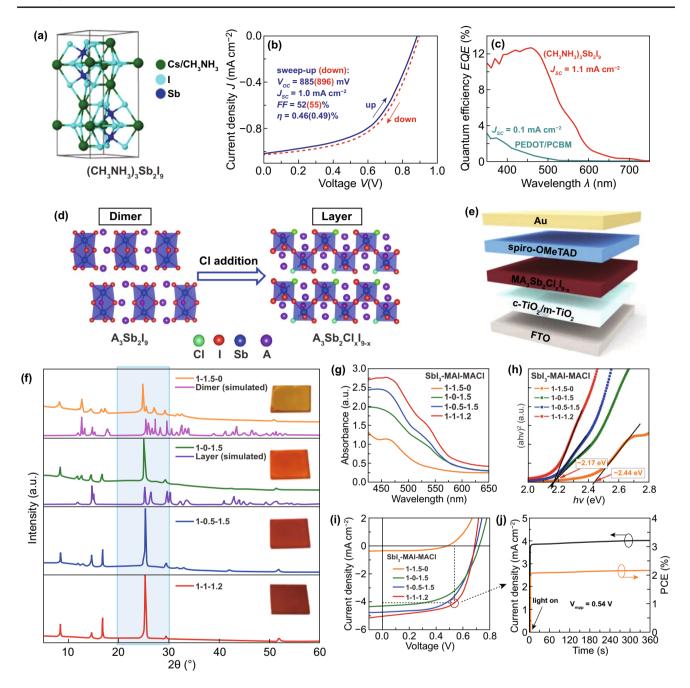
Taking Bi as the core element of the B position, Shockley et al. examined a series of MABiChX<sub>2</sub> (Ch = S, Se, Te; X = I, Br, Cl) compounds and found that  $CH_3NH_3BiSeI_2$  and CH<sub>3</sub>NH<sub>3</sub>BiSI<sub>2</sub> exhibited improved optical absorption and reduced bandgaps (1.3-1.4 eV) over CH<sub>3</sub>NH<sub>3</sub>PbI<sub>3</sub>, which were proved to be the optimal value for solar cell absorbers according to the Shockley–Queisser theory (Fig. 8c) [177]. These results suggested that the 3D AB(Ch, X)<sub>3</sub> perovskites represented by MABiSI<sub>2</sub> could be promising candidates of photovoltaic absorbers once they were successfully synthesized. Unfortunately, the subsequent feasibility assessment of the proposed 3D AB(Ch, X)<sub>3</sub> perovskites by Hong et al. via DFT calculations and solid-state reactions indicated that all of the as-proposed AB(Ch, X)<sub>3</sub> perovskites are thermodynamically unstable [34], and they tend to decompose into ternary and/or binary phases or form nonperovskite phases. Recently, the work of Li et al. has proved the instability of chalcogen-halogen hybrid perovskite through experimental and computational analysis, and they found that AB(Ch, X)<sub>3</sub> would be decomposed into a mixture of binary and ternary compounds (Sb<sub>2</sub>S<sub>3</sub> and MA<sub>3</sub>Sb<sub>2</sub>I<sub>9</sub>) soon after being synthesized [178]. Upon inspection, the target perovskites are impossible to be successfully synthesized as designed.

Finally, the researcher had to draw a conclusion that it may be a huge challenge to synthesize the proposed  $AB(Ch, X)_3$ perovskites due to their thermodynamic instability, which means there is still a long way for  $AB(Ch, X)_3$  perovskites to go for further applications in perovskite photovoltaic devices.

#### 3.2.3 0D Perovskite Derivative A<sub>2</sub>BX<sub>6</sub>

Previous analysis indicated that it is feasible to replace Pb of lead halide perovskites with tetravalent B(IV) substitutes. To accommodate the heterovalent substitute, the chemical formula needs to turn into  $A_2BX_6$ , which is derived from its ABX<sub>3</sub> perovskite structure by removing half of B-site cations. Because of the large charge difference between them, the  $A_2BX_6$  perovskite variant is sometimes referred to as the  $A_2B\Box X_6$ -type vacant ordered double perovskite [86, 179–181]. The B-site vacancies (denoted as  $\Box$ ) and the remaining B-site cations generally adopt a rock salt arrangement in the A2BX6 perovskite structure. Due to the absence of connectivity between the [BX<sub>6</sub>] octahedra, the A<sub>2</sub>BX<sub>6</sub> perovskite variants are actually 0D nonperovskites despite researchers still would like to call them perovskites. The optoelectronic properties of the  $A_2BX_6$ -type perovskite materials are rather different from those of 3D ABX<sub>3</sub> (B = Pb, Sn, and Ge) perovskites due to the isolated  $[BX_6]$ octahedra in  $A_2BX_6$  compounds. Among the  $A_2BX_6$  compounds [182–185],  $A_2SnI_6$  (A = Cs, MA) [182, 183] and Cs<sub>2</sub>TiBr<sub>6</sub> [181, 182] have been investigated for photovoltaic applications. These A<sub>2</sub>BX<sub>6</sub> compounds show intrinsic n-type conductivity. Compared to 3D CsSnI<sub>3</sub> with better defect tolerance, the A<sub>2</sub>BX<sub>6</sub>-type materials with I vacancies and Sn interstitial defects have deeper levels in their bandgaps owing to the strong covalent nature of the [SnI<sub>6</sub>] octahedron, seriously impacting optoelectronic performances of devices.

The vacancy-ordered  $A_2M(IV)X_6$  double perovskites was found to have suitable direct bandgaps. In 2016, Cao et al. found the spontaneous oxidative conversion of unstable CsSnI<sub>3</sub> to air-stable Cs<sub>2</sub>SnI<sub>6</sub> in air [183]. The Cs<sub>2</sub>SnI<sub>6</sub> perovskite was adopted as the light absorber layer of leadfree perovskite solar cell for the first time due to its small bandgap of 1.48 eV and high absorption coefficient, showing a PCE of about 1% with a  $V_{oc}$  of 0.51 V and a  $J_{sc}$  of 5.41 mA cm<sup>-2</sup> after optimizing the perovskite film thickness.



**Fig. 14** a Crystal structure of  $(CH_3NH_3)_3Sb_2I_9$  (space group P6<sub>3</sub>/mmc). b Illuminated *J*–*V* curves of  $(CH_3NH_3)_3Sb_2I_9$  solar cell measured with forward and backward scanning with a rate of 0.1 V s<sup>-1</sup>. c EQE measurement of the  $(CH_3NH_3)_3Sb_2I_9$  solar cell compared to the reference device of ITO/PEDOT/PCBM/ZnO-NP/Al. Reproduced with permission from Ref. [173] d Schematic plot of the Cl doping-induced transformation from the 0D dimer phase of A<sub>3</sub>Sb<sub>2</sub>I<sub>9</sub> to the 2D layered phase of A<sub>3</sub>Sb<sub>2</sub>Cl<sub>X</sub>I<sub>9–X</sub>. e Schematic structure of the as-fabricated PSC. f XRD patterns of the films deposited from precursors containing SbI<sub>3</sub>, MAI, and MACl with molar ratios of 1:1.5:0, 1:0.5:1.5, and 1:1:1.2. g Measured UV–vis absorbance spectra of the four types of films. h Tauc plots of the absorption coefficients for evaluating the bandgap values of the pure-iodine perovskites MA<sub>3</sub>Sb<sub>2</sub>I<sub>9</sub> and Cl-containing mixed-halide perovskites MA<sub>3</sub>Sb<sub>2</sub>Cl<sub>X</sub>I<sub>9–X</sub>. i *J*–*V* curves for the devices fabricated with the four kinds of perovskite films. j Steady-state photocurrent output for the device based on 1-1-1.2 film at the maximum power point (red circle). Maximum power point voltage V<sub>mpp</sub> is equal to 0.54 V. Reproduced with permission from Ref. [176]

Soon after, Cao et al. synthesized  $Cs_2SnI_6$  powder with a modified solution process and fabricated mesoporous solar cells [183]. They achieved a PCE of 0.96% by carefully

controlling ZnO nanorod length and pore size. Chang et al. reported a new material  $Cs_2SnI_{6-x}Br_x$  with mixed halides which provided desired bandgaps of ~1.3 to ~2.9 eV suitable

for solar cells via simple tune of Br component. They applied this perovskite material as light absorbing layer to PSCs and achieved an optimal conversion efficiency of 2.1% as x=2[184]. Recently,  $Cs_2TiBr_6$  thin films were prepared through a facile low-temperature vapor-based method and then incorporated into planar heterojunction PSCs [185]. Subsequently, Chen et al. also demonstrated that the  $Cs_2TiBr_6$ thin film has a suitable bandgap of 1.8 eV, a long and balanced carrier diffusion length, and an appropriate energy level, with which solar cells produced an efficiency of up to 3.3% [186].

#### 3.2.4 Double Perovskite $A_2B(I)B(III)X_6$

Lead-free halide double perovskites materials were known as "elpasolites" many years ago, whose name was from the mineral  $K_2NaAlF_6$ . In 2016, Giustino et al. counted the elements belonging to halide elpasolites [27]. As shown in Fig. 15, it can be clearly seen that 7 elements can occupy the A-site, and 8 elements including  $NH_3^+$  can occupy the B(I) site and 34 elements can occupy the B(III) site, while 5 elements containing the cyanide  $CN^-$  are able to occupy the X site. Although many of these compounds are available, it requires to satisfy some prerequisites for photovoltaic applications, such as suitable bandgap, high carrier mobility, low defect state and good thermodynamic stability. Through the element selection of B(I) site and B(III) site in the double perovskite, the bandgap can be well adjusted and thus exhibits excellent optoelectronic properties. For example, Cs<sub>2</sub>NaBiI<sub>6</sub> has a direct bandgap of 1.66 eV. Through element adjustment, Cs<sub>2</sub>AgInBr<sub>6</sub> with a direct bandgap of 1.50 eV and  $Cs_2InSbCl_6$  and  $Cs_2InBiCl_6$  with a direct bandgap of about 1.0 eV can be obtained. At present, the researchers have discovered the double perovskite material Cs<sub>2</sub>AgBiBr<sub>6</sub> possesses with a suitable bandgap of 1.95 eV, which can be used as light absorber in solar cells. To date, Cs<sub>2</sub>AgBiBr<sub>6</sub> is the most commonly used photovoltaic material in leadfree halide double perovskite-based solar cells [187–190]. Bein et al. fabricated Cs<sub>2</sub>AgBiBr<sub>6</sub> films with a spin coating method and incorporated them into solar cells for the first time in 2017 [187]. After optimizing synthesis conditions, the Cs<sub>2</sub>AgBiBr<sub>6</sub>-based solar cells without encapsulation showed a PCE of 2.43%, a  $V_{\rm oc}$  of exceeding 1 V and excellent stability in air. The fly in the ointment is that the device has a serious hysteresis effect.

In 2018, Xiao et al. prepared a transparent solution of  $Cs_2AgBiBr_6$  in DMSO and fabricated the  $Cs_2AgBiBr_6$  film using spin coating technique by low-pressure-assisted

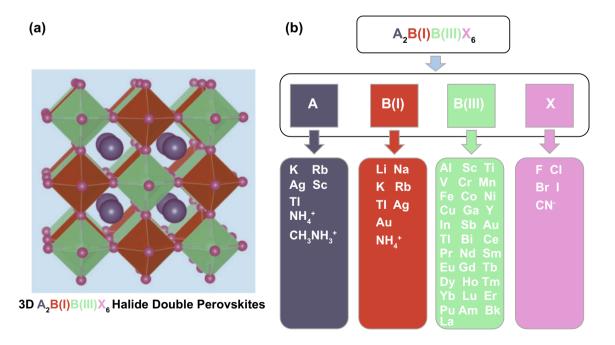
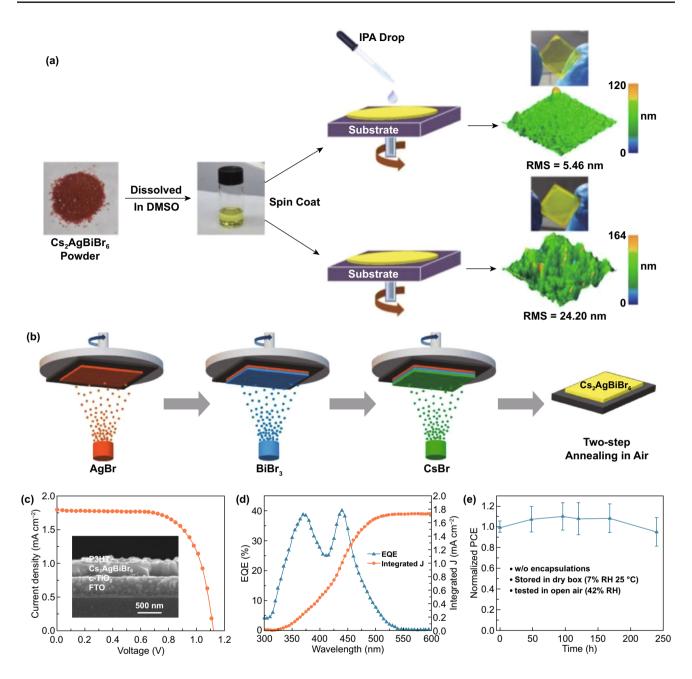


Fig. 15 Crystal structure of double perovskite  $A_2B(I)B(III)X_6$  (a) and the elements/functional groups that can form double perovskite  $A_2B(I)B(III)X_6$  (b)



**Fig. 16** a Schematic illustration of the spin coating process of  $Cs_2AgBiBr_4$  with and without antisolvent dropping program, and the morphology of the as-prepared film. Reproduced with permission from Ref. [189] b Scheme of sequential vapor deposition process. c J-V curve of the optimized solar cell. Inset: Cross-sectional SEM image of the device. d EQE spectrum and the integrated current density with AM 1.5G photon flux. e Evaluation of long-term stability of the solar cells stored in dry box. Reproduced with permission from Ref. [191]

solution processing under ambient conditions [188]. Differently from the conventional annealing method, the spincoated film was quickly moved to a low-pressure chamber pumped to 20 Pa, where the transparent film gradually turned to light yellow. A smooth morphology was obtained compared with the rough films prepared by conventional annealing methods. Finally, planar heterojunction solar cells were manufactured with optimized  $Cs_2AgBiBr_6$  films and P3HT hole transport layer, and a PCE of 1.44% was achieved.

Absorber	Method for preparing perovskite film	Device architecture	$V_{\rm oc}\left({\rm V} ight)$	$J_{\rm sc}$ (mA cm <sup>-2</sup> )	FF (%)	PCE (%)	References
Cs <sub>2</sub> AgBiBr <sub>6</sub>	Spin coating	c-TiO <sub>2</sub> /m-TiO <sub>2</sub> /perovskite/spiro- MeOTAD/Au	0.98	3.93	63	2.43	[187]
Cs <sub>2</sub> AgBiBr <sub>6</sub>	Low-pressure-assisted solution pro- cessing under ambient conditions	SnO <sub>2</sub> /Cs <sub>2</sub> AgBiBr <sub>6</sub> /P3HT/Au	1.04	1.78	78	1.44	[188]
Cs <sub>2</sub> AgBiBr <sub>6</sub>	Antisolvent dropping technology and post-annealing process	Cu-NiO/Cs <sub>2</sub> AgBiBr <sub>6</sub> /C <sub>60</sub> /BCP/Ag	1.00	3.23	68.4	2.21	[189]
Cs <sub>2</sub> AgBiBr <sub>6</sub>	Sequential vapor deposition method	c-TiO <sub>2</sub> /perovskite/P3HT/Au	-	-	-	1.37	[191]
Cs <sub>2</sub> AgBiBr <sub>6</sub>	Spin coating deposition and annealing at high temperature	c-TiO <sub>2</sub> /m-TiO <sub>2</sub> /perovskite/PTAA/ Au	1.02	1.84	67	1.26	[190]
Cs <sub>2</sub> AgBiBr <sub>6</sub>	Spin coating deposition and annealing at high temperature	c-TiO <sub>2</sub> /m-TiO <sub>2</sub> /perovskite/PCP- DTBT/Au	0.71	1.67	57	0.68	[190]
Cs <sub>2</sub> AgBiBr <sub>6</sub>	Spin coating deposition and annealing at high temperature	c-TiO <sub>2</sub> /m-TiO <sub>2</sub> /perovskite/spiro- MeOTAD/Au	0.64	2.45	57	0.90	[190]
Cs <sub>2</sub> NaBiI <sub>6</sub>	Spin coating	c-TiO <sub>2</sub> /m-TiO <sub>2</sub> /perovskite/spiro- MeOTAD/Au	0.47	1.99	44	0.42	[194]

Table 3 Photovoltaic parameters of PSCs based on double perovskite A2B(I)B(III)X6 absorbers

In a subsequent work, Wu et al. used antisolvent dropping method and post-annealing process to realize high-quality  $Cs_2AgBiBr_6$  films with ultra-smooth morphology, microsized grains, and high crystallinity (Fig. 16a). Then they fabricated inverted planar heterojunction solar cells with the as-prepared  $Cs_2AgBiBr_6$  films and got a high PCE of 2.23% [189]. It should be noted that the *J*–*V* hysteresis was clearly showed in the above-mentioned two works, which was closely related with the large amount of defects in  $Cs_2AgBiBr_6$  films. Grancini et al. precisely controlled the perovskite deposition parameters to obtain a highly uniform and compact  $Cs_2AgBiBr_6$  film, and modified the device interfaces with small molecular/polymeric hole-transporting materials to eliminate the hysteresis effect [190].

Recently, Liu et al. successfully prepared double perovskite  $Cs_2AgBiBr_6$  thin films through a sequential vapor deposition procedure (Fig. 16b) [191]. The as-fabricated thin films with pure double perovskite phase showed large grain sizes, uniform and smooth surface morphology along with a PL lifetime of 117 ns, indicative of a significant potential in photovoltaic applications. The solar cells with planar device structure obtained an optimal PCE of 1.37%, which maintained 90% of the initial efficiency after 240 h storage under ambient condition (Fig. 16c–e). In addition to Cs<sub>2</sub>AgBiBr<sub>6</sub>, Cs<sub>2</sub>NaBiI<sub>6</sub> has also been used as a light absorbing layer for PSCs and the device showed a good stability despite of a low efficiency of only 0.42% [192]. Relevant results for most types of double PSCs based on various device architectures are summarized in Table 3 [187–192].

At the initial design stage of lead-free halide double perovskite materials, researchers specifically emphasized the need to ensure the thermodynamic stability of the material [186–188]. Therefore, the halide double perovskite materials used in solar cells show excellent stability, which will be an outstanding advantage in practical application. In addition, the optical bandgap and other optoelectronic properties of the double perovskites can be optimized through the use of both B(I) and B(III) elements [186–194]. Thus, these characteristics make the halide double perovskite a good candidate for high-performance, stable and environmentally friendly solar cells.

#### **4** Conclusion and Prospect

In this review, we focused our attention on environmentally friendly lead-free perovskite materials and combed the related progress on theoretical and experimental works. Herein, all of lead-free perovskites consisting of Sn (II), Cu (II), Bi(III), Sb (III), Sn (IV), Ti (IV), and Ag(I)Bi(III) were introduced from the isovalent and heterovalent elements replacement perspectives. We summarized the material preparation, device performance and stability of each lead-free perovskite materials and presented their possible issues and potential development prospects. For Sn-based perovskites, this type of material has a relatively high absorption coefficient (close to  $1.80 \times 10^4$  cm<sup>-1</sup>), but the easy oxidation of Sn<sup>2+</sup> to Sn<sup>4+</sup> is also considered to be the main problem limiting the development of Sn-based PSCs. Similar to Sn-based perovskites, Ge-based perovskites also face the trouble of being easily decomposed by oxidation. In addition, compared with Sn<sup>2+</sup>, Bi and Sb are very stable when they are in the +3 valence state in the atmosphere. However, the efficiency of Bi- and Sb-based PSCs is still very low. Further optimization of their bandgaps as well as film morphology, manufacture methods and device structures are feasible solutions to further improve device performance. The transition metal perovskites represented by Cu-based perovskites also need to reduce their wide optical bandgap and improve their charge transporting properties to develop more efficient PSCs. Besides, the application of  $AB(Ch, X)_3$  perovskites for PSCs is facing great challenges due to the thermodynamic instability. In addition to the above-mentioned materials, the halide double perovskite has attracted people's attention because of its excellent stability and bandgap tunability.

In summary, we have reviewed the past experimental work and comprehensively understood the development and application prospects of current lead-free perovskite materials. Lead-free perovskites enable to avoid a high content of the toxic, polluting and bioaccumulative lead hazards and are more conducive to commercial production and application. At the same time, theoretical simulations have made important contributions to comprehending the fundamental physics behind the efficiency, stability, and carrier transport properties of lead-free PSCs. Using scientific theoretical calculations and reasonable solar cell preparation methods, we believe that the research on lead-free PSCs will soon have a clear breakthrough. Here, we are looking forward to the further development of lead-free perovskite materials and PSCs. Finally, we expect that the performance as well as the stability of lead-free perovskites, especially 2D layered perovskites, can be continuously improved to meet the needs of commercial development. In spite of slower development of lead-free perovskites than lead ones, we believe that the efficiency based on lead-free perovskite materials can break through 15% after further in-depth study, and we should keep warm toward this research.

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## References

- A. Kojima, K. Teshima, Y. Shirai, T. Miyasaka, Organometal halide perovskites as visible-light sensitizers for photovoltaic cells. J. Am. Chem. Soc. 131(17), 6050–6051 (2009). https:// doi.org/10.1021/ja809598r
- M.M. Lee, J. Teuscher, T. Miyasaka, T.N. Murakami, H.J. Snaith, Efficient hybrid solar cells based on meso-superstructured organometal halide perovskites. Science 338(6107), 643–647 (2012). https://doi.org/10.1126/science.1228604
- G. Xing, N. Mathews, S. Sun, S.S. Lim, Y.M. Lam et al., Long-range balanced electron- and hole-transport lengths in organic-inorganic CH<sub>3</sub>NH<sub>3</sub>PbI<sub>3</sub>. Science **342**(6156), 344–347 (2013). https://doi.org/10.1126/science.1243167
- S.D. Stranks, G.E. Eperon, G. Grancini, C. Menelaou, M.J.P. Alcocer et al., Electron-hole diffusion lengths exceeding 1 micrometer in an organometal trihalide perovskite absorber. Science 342(6156), 341–344 (2013). https://doi.org/10.1126/ science.1243982
- P. Docampo, J.M. Ball, M. Darwich, G.E. Eperon, H.J. Snaith, Efficient organometal trihalide perovskite planarheterojunction solar cells on flexible polymer substrates. Nat. Commun. 4, 2761–2766 (2013). https://doi.org/10.1038/ ncomms3761
- J.H. Heo, S.H. Im, J.H. Noh, T.N. Mandal, C.-S. Lim et al., Efficient inorganic-organic hybrid heterojunction solar

cells containing perovskite compound and polymeric hole conductors. Nat. Photon. **7**(6), 486–491 (2013). https://doi. org/10.1038/nphoton.2013.80

- J. Burschka, N. Pellet, S.-J. Moon, R. Humphry-Baker, P. Gao et al., Sequential deposition as a route to high-performance perovskite-sensitized solar cells. Nature **499**(7458), 316–319 (2013). https://doi.org/10.1038/nature12340
- P. Gao, M. Grätzel, M.K. Nazeeruddin, Organohalide lead perovskites for photovoltaic applications. Energy Environ. Sci. 7(8), 2448–2463 (2014). https://doi.org/10.1039/c4ee0 0942h
- O. Malinkiewicz, A. Yella, Y.H. Lee, G.M. Espallargas, M. Graetzel et al., Perovskite solar cells employing organic charge-transport layers. Nat. Photon. 8(2), 128–132 (2013). https://doi.org/10.1038/nphoton.2013.341
- W. Chen, Y. Wu, Y. Yue, J. Liu, W. Zhang et al., Efficient and stable large-area perovskite solar cells with inorganic charge extraction layers. Science **350**(6263), 944–948 (2015). https ://doi.org/10.1126/science.aad1015
- M. Sessolo, H.J. Bolink, Solar cells@ Perovskite solar cells join the major league. Science **350**(6263), 917 (2015). https ://doi.org/10.1126/science.aad5891
- J. Xu, A. Buin, A.H. Ip, W. Li, O. Voznyy et al., Perovskite-fullerene hybrid materials suppress hysteresis in planar diodes. Nat. Commun. 6, 7081 (2015). https://doi. org/10.1038/ncomms8081
- M.A. Green, K. Emery, Y. Hishikawa, W. Warta, E.D. Dunlop, Solar cell efficiency tables (version 46). Prog. Photovolt: Res. Appl. 23(7), 805–812 (2015). https://doi.org/10.1002/ pip.2637
- Z. Xiao, Q. Dong, C. Bi, Y. Shao, Y. Yuan et al., Solvent annealing of perovskite-induced crystal growth for photovoltaic-device efficiency enhancement. Adv. Mater. 26(37), 6503–6509 (2014). https://doi.org/10.1002/adma.201401685
- A. Mei, X. Li, L. Liu, Z. Ku, T. Liu et al., A hole-conductorfree, fully printable mesoscopic perovskite solar cell with high stability. Science 345(6194), 295–298 (2014). https:// doi.org/10.1126/science.1254763
- D. Liu, T.L. Kelly, Perovskite solar cells with a planar heterojunction structure prepared using room-temperature solution processing techniques. Nat. Photon. 8(2), 133–138 (2013). https://doi.org/10.1038/nphoton.2013.342
- C. Bi, Q. Wang, Y. Shao, Y. Yuan, Z. Xiao et al., Non-wetting surface-driven high-aspect-ratio crystalline grain growth for efficient hybrid perovskite solar cells. Nat. Commun. 6, 7747 (2015). https://doi.org/10.1038/ncomms8747
- D.P. McMeekin, G. Sadoughi, W. Rehman, G.E. Eperon, M. Saliba et al., A mixed-cation lead mixed-halide perovskite absorber for tandem solar cells. Science **351**(6269), 151–155 (2016). https://doi.org/10.1126/science.aad5845
- Y. Chen, T. Chen, L. Dai, Layer-by-layer growth of CH<sub>3</sub>NH<sub>3</sub>PbI<sub>(3-x)</sub>Cl<sub>x</sub> for highly efficient planar heterojunction perovskite solar cells. Adv. Mater. 27(6), 1053–1059 (2015). https://doi.org/10.1002/adma.201404147

- W.S. Yang, J.H. Noh, N.J. Jeon, Y.C. Kim, S. Ryu et al., High-performance photovoltaic perovskite layers fabricated through intramolecular exchange. Science 348(6420), 1234– 1237 (2015). https://doi.org/10.1126/science.aaa9272
- J. Wang, Y. Liu, X. Chen, C. Chen, P. Chen et al., Functional metal oxides in perovskite solar cells. ChemPhysChem 20(20), 2580–2586 (2019). https://doi.org/10.1002/cphc.201900447
- D. Bi, W. Tress, M.I. Dar, P. Gao, J. Luo et al., Efficient luminescent solar cells based on tailored mixed-cation perovskites. Sci. Adv. 2(1), e1501170 (2016). https://doi. org/10.1126/sciadv.1501170
- K. Meng, S. Gao, L. Wu, G. Wang, X. Liu et al., Two-dimensional organic-inorganic hybrid perovskite photonic films. Nano Lett. 16(7), 4166–4173 (2016). https://doi.org/10.1021/acs.nanolett.6b01046
- N.J. Jeon, H. Na, E.H. Jung, T.-Y. Yang, Y.G. Lee et al., A fluorene-terminated hole-transporting material for highly efficient and stable perovskite solar cells. Nat. Energy 3(8), 682–689 (2018). https://doi.org/10.1038/s41560-018-0200-6
- B. Hailegnaw, S. Kirmayer, E. Edri, G. Hodes, D. Cahen, Rain on methylammonium lead iodide based perovskites: Possible environmental effects of perovskite solar cells. J. Phys. Chem. Lett. 6(9), 1543–1547 (2015). https://doi. org/10.1021/acs.jpclett.5b00504
- R. Wang, J. Wang, S. Tan, Y. Duan, Z.-K. Wang et al., Opportunities and challenges of lead-free perovskite optoelectronic devices. Trends in Chem. 1(4), 368–379 (2019). https://doi. org/10.1016/j.trechm.2019.04.004
- F. Giustino, H.J. Snaith, Toward lead-free perovskite solar cells. ACS Energy Lett. 1(6), 1233–1240 (2016). https://doi. org/10.1021/acsenergylett.6b00499
- Z. Shi, J. Guo, Y. Chen, Q. Li, Y. Pan et al., Lead-free organic-inorganic hybrid perovskites for photovoltaic applications: recent advances and perspectives. Adv. Mater. 29(16), 1605005 (2017). https://doi.org/10.1002/adma.201605005
- S. Yang, W. Fu, Z. Zhang, H. Chen, C.-Z. Li, Recent advances in perovskite solar cells: efficiency, stability and lead-free perovskite. J. Mater. Chem. A 5(23), 11462–11482 (2017). https://doi.org/10.1039/c7ta00366h
- P. Xu, S. Chen, H.-J. Xiang, X.-G. Gong, S.-H. Wei, Influence of defects and synthesis conditions on the photovoltaic performance of perovskite semiconductor CsSnI<sub>3</sub>. Chem. Mater. 26(2), 6068–6073 (2014). https://doi.org/10.1021/cm503122j
- S.F. Hoefler, G. Trimmel, T. Rath, Progress on lead-free metal halide perovskites for photovoltaic applications: a review. Monatsh. Chem. 148(5), 795–826 (2017). https:// doi.org/10.1007/s00706-017-1933-9
- M. Lyu, J.-H. Yun, P. Chen, M. Hao, L. Wang, Addressing toxicity of lead: progress and applications of low-toxic metal halide perovskites and their derivatives. Adv. Energy Mater. 7(15), 1602512–1602537 (2017). https://doi.org/10.1002/ aenm.201602512
- W. Ming, H. Shi, M.-H. Du, Large dielectric constant, high acceptor density, and deep electron traps in perovskite solar

cell material CsGeI<sub>3</sub>. J. Mater. Chem. A **4**(13), 13852–13875 (2016). https://doi.org/10.1039/C6TA04685A

- 34. F. Hong, B. Saparov, W. Meng, Z. Xiao, D.B. Mitzi et al., Viability of lead-free perovskites with mixed chalcogen and halogen anions for photovoltaic applications. J. Phys. Chem. C 120(12), 6435–6441 (2016). https://doi.org/10.1021/acs. jpcc.6b00920
- G.E. Eperon, S.D. Stranks, C. Menelaou, M.B. Johnston, L.M. Herz et al., Formamidinium lead trihalide: a broadly tunable perovskite for efficient planar heterojunction solar cells. Energy Environ. Sci. 7(3), 982–989 (2014). https://doi. org/10.1039/c3ee43822h
- 36. P. Sun, Q. Li, L. Yang, Z. Li, Theoretical insights into a potential lead-free hybrid perovskite: substituting Pb<sup>2+</sup> with Ge<sup>2+</sup>. Nanoscale 8(3), 1503–1513 (2016). https://doi. org/10.1039/c5nr05337d
- Y. Zhao, K. Zhu, Organic-inorganic hybrid lead halide perovskites for optoelectronic and electronic applications. Chem. Soc. Rev. 45(3), 655–689 (2016). https://doi.org/10.1039/ c4cs00458b
- N. Pellet, P. Gao, G. Gregori, T.-Y. Yang, M.K. Nazeeruddin et al., Mixed-organic-cation perovskite photovoltaics for enhanced solar-light harvesting. Angew. Chem. Int. Ed. 53(12), 3151–3157 (2014). https://doi.org/10.1002/ anie.201309361
- N.H. Tiep, Z. Ku, H.J. Fan, Recent advances in improving the stability of perovskite solar cells. Adv. Energy Mater. 6(3), 1501420–1501456 (2016). https://doi.org/10.1002/ aenm.201501420
- 40. Y. Zhang, J. Yin, M.R. Parida, G.H. Ahmed, J. Pan et al., Direct-indirect nature of the bandgap in lead-free perovskite nanocrystals. J. Phys. Chem. Lett. 8(1), 3173–3188 (2017). https://doi.org/10.1021/acs.jpclett.7b01381
- N.J. Jeon, J.H. Noh, W.S. Yang, Y.C. Kim, S. Ryu et al., Compositional engineering of perovskite materials for highperformance solar cells. Nature 517(7535), 476–480 (2015). https://doi.org/10.1038/nature14133
- D.E. Starr, G. Sadoughi, E. Handick, R.G. Wilks, J.H. Alsmeier et al., Direct observation of an inhomogeneous chlorine distribution in CH<sub>3</sub>NH<sub>3</sub>PbI<sub>3-x</sub>Cl<sub>x</sub> layers: surface depletion and interface enrichment. Energy Environ. Sci. 8(5), 1609–1615 (2015). https://doi.org/10.1039/c5ee00403a
- 43. S. Dharani, H.A. Dewib, R.R. Prabhakarb, T. Baikieb, C. Shic et al., Incorporation of Cl in sequentially deposited lead halide perovskite films for highly efficient mesoporous solar cells. Nanoscale 6(22), 13854–13860 (2014). https://doi.org/10.1039/C4NR04007D
- W. Zhang, M. Saliba, D.T. Moore, S.K. Pathak, M.T. Hörantner et al., Ultrasmooth organic-inorganic perovskite thin-film formation and crystallization for efficient planar heterojunction solar cells. Nat. Commun. 6, 6142–6151 (2015). https:// doi.org/10.1038/ncomms7142
- 45. J. Qing, H.-T. Chandran, Y.-H. Cheng, X.-K. Liu, H.-W. Li et al., Chlorine incorporation for enhanced performance of planar perovskite solar cell based on lead acetate precursor.

ACS Appl. Mater. Interfaces. **7**(41), 23110–23116 (2015). https://doi.org/10.1021/acsami.5b06819

- 46. X. Lu, Y. Wang, C.C. Stoumpos, Q. Hu, X. Guo et al., Enhanced structural stability and photo responsiveness of CH<sub>3</sub>NH<sub>3</sub>SnI<sub>3</sub> perovskite via pressure-induced amorphization and recrystallization. Adv. Mater. 28(39), 8663–8668 (2016). https://doi.org/10.1002/adma.201600771
- M. Jiang, J. Wu, F. Lan, Q. Tao, D. Gao et al., Enhancing the performance of planar organo-lead halide perovskite solar cells by using a mixed halide source. J. Mater. Chem. A 3(3), 963–967 (2015). https://doi.org/10.1039/c4ta05373g
- 48. L. Huang, Z. Hu, G. Yue, J. Liu, X. Cui et al., CH<sub>3</sub>NH<sub>3</sub>PbI<sub>3-x</sub>Cl<sub>x</sub> films with coverage approaching 100% and with highly oriented crystal domains for reproducible and efficient planar heterojunction perovskite solar cells. Phys. Chem. Chem. Phys. **17**(34), 22015–22022 (2015). https://doi. org/10.1039/c5cp03934g
- T.G. Kim, S.W. Seo, H. Kwon, J. Hahn, J.W. Kim, Influence of halide precursor type and its composition on the electronic properties of vacuum deposited perovskite films. Phys. Chem. Chem. Phys. 17(37), 24342–24348 (2015). https://doi.org/10.1039/c5cp04207k
- J. Albero, A.M. Asiri, H. Garcia, Influence of the composition of hybrid perovskites on their performance in solar cells. J. Mater. Chem. A 4(12), 4353–4364 (2016). https:// doi.org/10.1039/c6ta00334f
- B. Ghosh, S. Chakraborty, H. Wei, C. Guet, S. Li et al., Poor photovoltaic performance of Cs<sub>3</sub>Bi<sub>2</sub>I<sub>9</sub>: an insight through first-principles calculations. J. Phys. Chem. C 121(32), 17062–17081 (2017). https://doi.org/10.1021/acs.jpcc.7b035 01
- 52. Y. Sun, J. Shi, J. Lian, W. Gao, M.L. Agiorgousis et al., Discovering lead-free perovskite solar materials with a splitanion approach. Nanoscale 8(12), 6284–6290 (2016). https://doi.org/10.1039/c5nr04310g
- G.E. Eperon, C.E. Beck, H.J. Snaith, Cation exchange for thin film lead iodide perovskite interconversion. Mater. Horiz. 3(1), 63–71 (2016). https://doi.org/10.1039/c5mh00170f
- J.H. Heo, S.H. Im, Highly reproducible, efficient hysteresisless CH<sub>3</sub>NH<sub>3</sub>PbI<sub>3-x</sub>Cl<sub>x</sub> planar hybrid solar cells without requiring heat-treatment. Nanoscale 8(5), 2554–2560 (2016). https://doi.org/10.1039/c5nr08458j
- T.M. Brenner, D.A. Egger, L. Kronik, G. Hodes, D. Cahen, Hybrid organic–inorganic perovskites: low-cost semiconductors with intriguing charge-transport properties. Nat. Rev. Mater. 1, 15007–15023 (2015). https://doi.org/10.1038/natre vmats.2015.7
- N.K. Noel, S.D. Stranks, A. Abate, C. Wehrenfennig, S. Guarnera et al., Lead-free organic-inorganic tin halide perovskites for photovoltaic applications. Energy Environ. Sci. 7(9), 3061–3068 (2014). https://doi.org/10.1039/c4ee01076k
- 57. N. Leblanc, N. Mercier, L. Zorina, S. Simonov, P. Auban-Senzier et al., Large spontaneous polarization and clear hysteresis loop of a room-temperature hybrid ferroelectric based on mixed-halide BiI<sub>3</sub>Cl<sub>2</sub> polar chains and methylviologen

dication. J. Am. Chem. Soc. **133**(38), 14924–14927 (2011). https://doi.org/10.1021/ja206171s

- W. Bi, N. Leblanc, N. Mercier, P. Auban-Senzier, C. Pasquier, Thermally induced Bi(III) lone pair stereoactivity: ferroelectric phase transition and semiconducting properties of (MV)BiBr 5(MV = methylviologen). Chem. Mater. 21(18), 4099–4101 (2009). https://doi.org/10.1021/cm9016003
- B.-W. Park, B. Philippe, X. Zhang, H. Rensmo, G. Boschloo et al., Bismuth based hybrid perovskites A<sub>3</sub>Bi<sub>2</sub>I<sub>9</sub> (a: methylammonium or cesium) for solar cell application. Adv. Mater. 27(43), 6806–6813 (2015). https://doi.org/10.1002/ adma.201501978
- T. Krishnamoorthy, H. Ding, C. Yan, W.L. Leong, T. Baikie et al., Lead-free germanium iodide perovskite materials for photovoltaic applications. J. Mater. Chem. A 3(47), 23829– 23832 (2015). https://doi.org/10.1039/c5ta05741h
- C.C. Stoumpos, L. Frazer, D.J. Clark, Y.S. Kim, S.H. Rhim et al., Hybrid germanium iodide perovskite semiconductors: active lone pairs, structural distortions, direct and indirect energy gaps, and strong nonlinear optical properties. J. Am. Chem. Soc. 137(21), 6804–6819 (2015). https://doi. org/10.1021/jacs.5b01025
- B. Saparov, F. Hong, J.-P. Sun, H.-S. Duan, W. Meng et al., Thin-film preparation and characterization of Cs<sub>3</sub>Sb<sub>2</sub>I<sub>9</sub>: a lead-free layered perovskite semiconductor. Chem. Mater. 27(16), 5622–5632 (2015). https://doi.org/10.1021/acs. chemmater.5b01989
- D. Cortecchia, H.A. Dewi, J. Yin, A. Bruno, S. Chen et al., Lead-free MA2CuClxBr 4–x hybrid perovskites. Inorg. Chem. 55(3), 1044–1052 (2016). https://doi.org/10.1021/ acs.inorgchem.5b01896
- 64. G. Giorgi, J.-I. Fujisawa, H. Segawa, K. Yamashita, Small photocarrier effective masses featuring ambipolar transport in methylammonium lead iodide perovskite: a density functional analysis. J. Phys. Chem. Lett. 4(24), 4213–4216 (2013). https ://doi.org/10.1021/jz4023865
- 65. J. Feng, B. Xiao, Crystal structures, optical properties, and effective mass tensors of CH<sub>3</sub>NH<sub>3</sub>PbX<sub>3</sub> (X = I and Br) phases predicted from HSE06. J. Phys. Chem. Lett. 5(7), 1278–1282 (2014). https://doi.org/10.1021/jz500480m
- M.R. Filip, F. Giustino, Computational screening of homovalent lead substitution in organic-inorganic halide perovskites. J. Phys. Chem. C 120(1), 166–173 (2015). https://doi.org/10.1021/acs.jpcc.5b11845
- Z. Xiao, Z. Song, Y. Yan, From lead halide perovskites to lead-free metal halide perovskites and perovskite derivatives. Adv. Mater. 31(47), 1803792–1803813 (2019). https://doi. org/10.1002/adma.201803792
- P. Umari, E. Mosconi, F. De Angelis, Relativistic GW calculations on CH<sub>3</sub>NH<sub>3</sub>PbI<sub>3</sub> and CH<sub>3</sub>NH<sub>3</sub>SnI<sub>3</sub> perovskites for solar cell applications. Sci. Rep. 4, 4467–4473 (2014). https ://doi.org/10.1038/srep04467
- 69. F. Li, C. Zhang, J.H. Huang, H. Fan, H. Wang et al., A cationexchange approach for the fabrication of efficient methylammonium tin iodide perovskite solar cells. Angew. Chem.

Int. Ed. 58(20), 6688–6692 (2019). https://doi.org/10.1002/ anie.201902418

- F. Hao, C.C. Stoumpos, D.H. Cao, R.P.H. Chang, M.G. Kanatzidis, Lead-free solid-state organic-inorganic halide perovskite solar cells. Nat. Photon. 8(6), 489–494 (2014). https://doi.org/10.1038/nphoton.2014.82
- M.H. Kumar, S. Dharani, W.L. Leong, P.P. Boix, R.R. Prabhakar et al., Lead-free halide perovskite solar cells with high photocurrents realized through vacancy modulation. Adv. Mater. 26(41), 7122–7127 (2014). https://doi.org/10.1002/adma.201401991
- J.H. Noh, S.H. Im, J.H. Heo, T.N. Mandal, S.I. Seok, Chemical management for colorful, efficient, and stable inorganicorganic hybrid nanostructured solar cells. Nano Lett. 13(4), 1764–1769 (2013). https://doi.org/10.1021/nl400349b
- T. Yokoyama, D.H. Cao, C.C. Stoumpos, T.B. Song, Y. Sato et al., Overcoming short-circuit in lead-free CH<sub>3</sub>NH<sub>3</sub>SnI<sub>3</sub> perovskite solar cells via kinetically controlled gas-solid reaction film fabrication process. J. Phys. Chem. Lett. 7(5), 776–782 (2016). https://doi.org/10.1021/acs.jpclett.6b00118
- 74. F. Hao, C.C. Stoumpos, P. Guo, N. Zhou, T.J. Marks et al., Solvent-mediated crystallization of CH<sub>3</sub>NH<sub>3</sub>SnI<sub>3</sub> films for heterojunction depleted perovskite solar cells. J. Am. Chem. Soc. 137(35), 11445–11452 (2015). https://doi.org/10.1021/ jacs.5b06658
- M. Weiss, J. Horn, C. Richter, D. Schlettwein, Preparation and characterization of methylammonium tin iodide layers as photovoltaic absorbers. Phys. Status Solidi A 213(4), 975–981 (2016). https://doi.org/10.1002/pssa.201532594
- S. Chen, A. Walsh, X.G. Gong, S.-H. Wei, Classification of lattice defects in the kesterite Cu<sub>2</sub>ZnSnS<sub>4</sub> and Cu<sub>2</sub>ZnSnSe<sub>4</sub> earth-abundant solar cell absorbers. Adv. Mater. 25(11), 1522–1539 (2013). https://doi.org/10.1002/adma.201203146
- M.C. Jung, S.R. Raga, Y. Qi, Properties and solar cell applications of Pb-free perovskite films formed by vapor deposition. RSC Adv. 6(4), 2819–2825 (2016). https://doi.org/10.1039/ c5ra21291j
- D.E. Scaife, P.F. Weller, W.G. Fisher, Crystal preparation and properties of cesium tin(ii) trihalides. J. Solid State Chem. 9(3), 308–314 (1974). https://doi.org/10.1016/0022-4596(74)90088-7
- Z. Chen, J.J. Wang, Y. Ren, C. Yu, K. Shum, Schottky solar cells based on CsSnI<sub>3</sub> thin-films. Appl. Phys. Lett. **101**(9), 093901–093904 (2012). https://doi.org/10.1063/1.4748888
- D. Sabba, H.K. Mulmudi, R.R. Prabhakar, T. Krishnamoorthy, T. Baikie et al., Impact of anionic Br- substitution on open circuit voltage in lead free perovskite (CsSnI<sub>3-x</sub>Br<sub>x</sub>) solar cells. J. Phys. Chem. C **119**(4), 1763–1767 (2015). https ://doi.org/10.1021/jp5126624
- Y. Zhou, H.F. Garces, B.S. Senturk, A.L. Ortiz, N.P. Padture, Roomtemperature "one-pot" solution synthesis of nanoscale CsSnI<sub>3</sub> orthorhombic perovskite thin films andparticles. Mater. Lett. **110**, 127–129 (2013). https://doi.org/10.1016/j. matlet.2013.08.011
- S. Dharani, H.K. Mulmudi, N. Yantara, P.T. Thu-Trang, N.G. Park et al., High efficiency electrospun TiO<sub>2</sub> nanofiber based

hybrid organic-inorganic perovskite solar cell. Nanoscale **6**(3), 1675–1679 (2014). https://doi.org/10.1039/c3nr04857h

- K. Shum, Z. Chen, J. Qureshi, C. Yu, J.J. Wang et al., Synthesis and characterization of CsSNi<sub>3</sub> thin films. Appl. Phys. Lett. 96(22), 221903 (2010). https://doi.org/10.1063/1.34425 11
- I. Chung, J.H. Song, J. Im, J. Androulakis, C.D. Malliakas et al., CsSnI<sub>3</sub>: semiconductor or metal? High electrical conductivity and strong near-infrared photoluminescence from a single material. High hole mobility and phase-transitions. J. Am. Chem. Soc. **134**(20), 8579–8587 (2012). https://doi. org/10.1021/ja301539s
- K.P. Marshall, R.I. Walton, R.A. Hatton, Tin perovskite/ fullerene planar layer photovoltaics: improving the efficiency and stability of lead-free devices. J. Mater. Chem. A 3(21), 11631–11640 (2015). https://doi.org/10.1039/c5ta02950c
- L. Liang, P. Gao, Lead-free hybrid perovskite absorbers for viable application: can we eat the cake and have it too? Adv. Sci. 5(2), 1700331–1700364 (2018). https://doi.org/10.1002/ advs.201700331
- S.J. Lee, S.S. Shin, Y.C. Kim, D. Kim, T.K. Ahn et al., Fabrication of efficient formamidinium tin iodide perovskite solar cells through SnF<sub>2</sub>-pyrazine complex. J. Am. Chem. Soc. **138**(12), 3974–3977 (2016). https://doi.org/10.1021/jacs.6b00142
- Z. Zhao, F. Gu, Y. Li, W. Sun, S. Ye et al., Mixed-organiccation tin iodide for lead-free perovskite solar cells with an efficiency of 8.12. Adv. Sci. 4(11), 1700204–1700210 (2017). https://doi.org/10.1002/advs.201700204
- W. Ke, C.C. Stoumpos, M. Zhu, L. Mao, I. Spanopoulos et al., Enhanced photovoltaic performance and stability with a new type of hollow 3D perovskite {en}FASnI<sub>3</sub>. Sci. Adv. 3(8), e1701293–e1701301 (2017). https://doi.org/10.1126/sciad v.1701293
- 90. K.P. Marshall, M. Walker, R.I. Walton, R.A. Hatton, Enhanced stability and efficiency in hole-transport-layer-free CsSnI<sub>3</sub> perovskite photovoltaics. Nat. Energy 1(12), 16178– 16186 (2016). https://doi.org/10.1038/nenergy.2016.178
- M. Zhang, M. Lyu, J.H. Yun, M. Noori, X. Zhou et al., Low-temperature processed solar cells with formamidinium tin halide perovskite/fullerene heterojunctions. Nano Res. 9(6), 1570–1577 (2016). https://doi.org/10.1007/s1227 4-016-1051-8
- R.L. Milot, G.E. Eperon, T. Green, H.J. Snaith, M.B. Johnston et al., Radiative monomolecular recombination boosts amplified spontaneous emission in HC(NH<sub>2</sub>)<sub>2</sub>SnI<sub>3</sub> perovskite films. J. Phys. Chem. Lett. 7(20), 4178–4184 (2016). https://doi.org/10.1021/acs.jpclett.6b02030
- Y. Dang, Y. Zhou, X. Liu, D. Ju, S. Xia, H. Xia, X. Tao, Formation of hybrid perovskite tin iodide single crystals by top-seeded solution growth. Angew. Chem. Int. Ed. 55(10), 3447–3450 (2016). https://doi.org/10.1002/anie.201511792
- 94. D.B. Mitzi, K. Liang, Synthesis, resistivity, and thermal properties of the cubic perovskite NH<sub>2</sub>CH<sub>5</sub>NH<sub>2</sub>SnI<sub>3</sub> and related systems. J. Solid State Chem. **134**(2), 376–381 (1997). https://doi.org/10.1006/jssc.1997.7593

- 95. Z. Zhu, C.C. Chueh, N. Li, C. Mao, A.K.-Y. Jen, Realizing efficient lead-free formamidinium tin triiodide perovskite solar cells via a sequential deposition route. Adv. Mater. **30**(6), 1703800–1703808 (2018). https://doi.org/10.1002/ adma.201703800
- W. Liao, D. Zhao, Y. Yu, C.R. Grice, C. Wang et al., Leadfree inverted planar formamidinium tin triiodide perovskite solar cells achieving power conversion efficiencies up to 622. Adv. Mater. 28(42), 9333–9340 (2016). https://doi. org/10.1002/adma.201602992
- 97. W. Ke, C.C. Stoumpos, J.L. Logsdon, M.R. Wasielewski, Y. Yan et al., Tio<sub>2</sub>-zns cascade electron transport layer for efficient formamidinium tin iodide perovskite solar cells. J. Am. Chem. Soc. **138**(45), 14998–15003 (2016). https://doi. org/10.1021/jacs.6b08790
- F. Wang, J. Ma, F. Xie, L. Li, J. Chen et al., Organic cationdependent degradation mechanism of organotin halide perovskites. Adv. Funct. Mater. 26(20), 3417–3423 (2016). https ://doi.org/10.1002/adfm.201505127
- T.M. Koh, T. Krishnamoorthy, N. Yantara, C. Shi, W.L. Leong et al., Formamidinium tin-based perovskite with low Eg for photovoltaic applications. J. Mater. Chem. A 3(29), 14996–15000 (2015). https://doi.org/10.1039/c5ta00190k
- F. Gu, S. Ye, Z. Zhao, H. Rao, Z. Liu et al., Improving performance of lead-free formamidinium tin triiodide perovskite solar cells by tin source purification. Sol. RRL 2(10), 1870217 (2018). https://doi.org/10.1002/solr.201870217
- Z. Lin, C. Liu, G. Liu, J. Yang, X. Duan et al., Efficient inverted tin-based perovskite solar cells via bidentate coordination effect of 8-Hydroxyquinoline. Chem. Commun. 56(28), 4007–4010 (2020). https://doi.org/10.1039/d0cc0 1106a
- 102. J. Cao, Q. Tai, P. You, G. Tang, T. Wang et al., Enhanced performance of tin-based perovskite solar cells induced by an ammonium hypophosphite additive. J. Mater. Chem. A 7(46), 26580–26585 (2019). https://doi.org/10.1039/c9ta08679j
- 103. T. Wu, X. Liu, X. He, Y. Wang, X. Meng et al., Efficient and stable tin-based perovskite solar cells by introducing  $\pi$ -conjugated lewis base. Sci. China Chem. **63**(1), 107–115 (2019). https://doi.org/10.1007/s11426-019-9653-8
- 104. X. Meng, T. Wu, X. Liu, X. He, T. Noda et al., Highly reproducible and efficient FASnI<sub>3</sub> perovskite solar cells fabricated with volatilizable reducing solvent. J. Phys. Chem. Lett. 11(8), 2965–2971 (2020). https://doi.org/10.1021/acs.jpcle tt.0c00923
- 105. M. Saliba, T. Matsui, K. Domanski, J.-Y. Seo, A. Ummadisingu et al., Incorporation of rubidium cations into perovskite solar cells improves photovoltaic performance. Science 354(6309), 206–209 (2016). https://doi.org/10.1126/scien ce.aah5557
- 106. N.J. Jeon, J.H. Noh, Y.C. Kim, W.S. Yang, S. Ryu et al., Solvent engineering for high-performance inorganic-organic hybrid perovskite solar cells. Nat. Mater. 13(9), 897–903 (2014). https://doi.org/10.1038/nmat4014
- 107. N. Ahn, D.-Y. Son, I.-H. Jang, S.M. Kang, M. Choi et al., Highly reproducible perovskite solar cells with average

efficiency of 18.3% and best efficiency of 19.7% fabricated via lewis base adduct of lead(ii) iodide. J. Am. Chem. Soc. **137**(27), 8696–8699 (2015). https://doi.org/10.1021/ jacs.5b04930

- 108. W. Ke, C.C. Stoumpos, I. Spanopoulos, L. Mao, M. Chen et al., Efficient lead-free solar cells based on hollow {en} MASnI<sub>3</sub> perovskites. J. Am. Chem. Soc. **139**(41), 14800– 14806 (2017). https://doi.org/10.1021/jacs.7b09018
- 109. W. Ke, C.C. Stoumpos, I. Spanopoulos, M. Chen, M.R. Wasielewski et al., Diammonium cations in the FASnI<sub>3</sub> perovskite structure lead to lower dark currents and more efficient solar cells. ACS Energy Lett. **3**(7), 1470–1476 (2018). https://doi.org/10.1021/acsenergylett.8b00687
- 110. X. Li, D. Bi, C. Yi, J.D. Décoppet, J. Luo et al., A vacuum flash-assisted solution process for high-efficiency large-area perovskite solar cells. Science 353, 58–62 (2016). https://doi. org/10.1126/science.aaf8060
- F. Xu, T. Zhang, G. Li, Y. Zhao, Mixed cation hybrid lead halide perovskites with enhanced performance and stability. J. Mater. Chem. A 5(23), 11450–11461 (2017). https://doi. org/10.1039/c7ta00042a
- 112. H. Tan, A. Jain, O. Voznyy, X. Lan, F.P.G. Arquer et al., Efficient and stable solution-processed planar perovskite solar cells via contact passivation. Science **355**(6326), 722–726 (2017). https://doi.org/10.1126/science.aai9081
- 113. W.S. Yang, B.-W. Park, E.H. Jung, N.J. Jeon, Y.C. Kim et al., Iodide management in formamidinium-lead-halide-based perovskite layers for efficient solar cells. Science **356**(6345), 1376–1379 (2017). https://doi.org/10.1126/science.aan2301
- 114. X. Liu, Z. Yang, C.C. Chueh, A. Rajagopal, S.T. Williams et al., Improved efficiency and stability of Pb-Sn binary perovskite solar cells by cs substitution. J. Mater. Chem. A 4(46), 17939–17945 (2016). https://doi.org/10.1039/c6ta07712a
- 115. I.C. Smith, E.T. Hoke, D. Solis-Ibarra, M.D. McGehee, H.I. Karunadasa, A layered hybrid perovskite solar-cell absorber with enhanced moisture stability. Angew. Chem. Int. Ed. 53(42), 11232–11235 (2014). https://doi.org/10.1002/ anie.201406466
- 116. W. Peng, J. Yin, K.T. Ho, O. Ouellette, M. De Bastiani et al., Ultralow self-doping in two-dimensional hybrid perovskite single crystals. Nano Lett. 17(8), 4759–4767 (2017). https:// doi.org/10.1021/acs.nanolett.7b01475
- 117. Y. Lin, Y. Bai, Y. Fang, Q. Wang, Y. Deng et al., Suppressed ion migration in low-dimensional perovskites. ACS Energy Lett. 2(7), 1571–1572 (2017). https://doi.org/10.1021/acsen ergylett.7b00442
- 118. C.-M. Tsai, Y.-P. Lin, M.K. Pola, S. Narra, E. Jokar et al., Control of crystal structures and optical properties with hybrid formamidinium and 2-hydroxyethylammonium cations for mesoscopic carbon-electrode tin-based perovskite solar cells. ACS Energy Lett. 3(9), 2077–2085 (2018). https ://doi.org/10.1021/acsenergylett.8b01046
- 119. E. Jokar, C.H. Chien, C.M. Tsai, A. Fathi, E.W. Diau, Robust tin-based perovskite solar cells with hybrid organic cations to attain efficiency approaching 10%. Adv. Mater. **31**(2), e1804835 (2019). https://doi.org/10.1002/adma.201804835

- 120. D.H. Cao, C.C. Stoumpos, T. Yokoyama, J.L. Logsdon, T.-B. Song et al., Thin films and solar cells based on semiconducting two-dimensional ruddlesden-popper (CH<sub>3</sub>(CH<sub>2</sub>)<sub>3</sub>NH<sub>3</sub>)<sub>2</sub>(CH<sub>3</sub>NH<sub>3</sub>)<sub>n-1</sub>Sn<sub>n</sub>I<sub>3n+1</sub> perovskites. ACS Energy Lett. 2(5), 982–990 (2017). https://doi.org/10.1021/ acsenergylett.7b00202
- 121. K. Yao, X. Wang, Y. Xu, F. Li, L. Zhou, Multilayered perovskite materials based on polymeric-ammonium cations for stable large-area solar cell. Chem. Mater. 28(9), 3131–3138 (2016). https://doi.org/10.1021/acs.chemmater.6b00711
- 122. C. Ma, C. Leng, Y. Ji, X. Wei, K. Sun et al., 2D/3D perovskite hybrids as moisture-tolerant and efficient light absorbers for solar cells. Nanoscale 8(43), 18309–18314 (2016). https:// doi.org/10.1039/c6nr04741f
- 123. F. Wang, X. Jiang, H. Chen, Y. Shang, H. Liu et al., 2D-quasi-2D-3D hierarchy structure for tin perovskite solar cells with enhanced efficiency and stability. Joule 2(12), 2732–2743 (2018). https://doi.org/10.1016/j.joule.2018.09.012
- 124. X. Zhang, G. Wu, W. Fu, M. Qin, W. Yang et al., Orientation regulation of phenylethylammonium cation based 2D perovskite solar cell with efficiency higher than 11%. Adv. Energy Mater. 8(14), 1702498 (2018). https://doi.org/10.1002/ aenm.201702498
- 125. A.Z. Chen, M. Shiu, J.H. Ma, M.R. Alpert, D. Zhang et al., Origin of vertical orientation in two-dimensional metal halide perovskites and its effect on photovoltaic performance. Nat. Commun. 9(1), 1336 (2018). https://doi.org/10.1038/s4146 7-018-03757-0
- 126. J. Qiu, Y. Xia, Y. Zheng, W. Hui, H. Gu et al., 2D intermediate suppression for efficient ruddlesden-popper (RP) phase lead-free perovskite solar cells. ACS Energy Lett. 4(7), 1513– 1520 (2019). https://doi.org/10.1021/acsenergylett.9b00954
- 127. Y. Liao, H. Liu, W. Zhou, D. Yang, Y. Shang et al., Highly oriented low-dimensional tin halide perovskites with enhanced stability and photovoltaic performance. J. Am. Chem. Soc. **139**(19), 6693–6699 (2017). https://doi. org/10.1021/jacs.7b01815
- H. Xu, Y. Jiang, T. He, S. Li, H. Wang et al., Orientation regulation of tin-based reduced-dimensional perovskites for highly efficient and stable photovoltaics. Adv. Funct. Mater. 29(47), 1807696 (2019). https://doi.org/10.1002/adfm.20180 7696
- 129. J. Wang, H. Shen, W. Li, S. Wang, J. Li et al., The role of chloride incorporation in lead-free 2D perovskite (BA)<sub>2</sub>SnI<sub>4</sub>: morphology, photoluminescence, phase transition, and charge transport. Adv. Sci. 6(5), 1802019 (2019). https://doi. org/10.1002/advs.201802019
- 130. M. Chen, M.G. Ju, M.Y. Hu, Z.H. Dai, Y. Hu et al., Lead-free dion-jacobson tin halide perovskites for photovoltaics. ACS Energy Lett. 4(1), 276–277 (2019). https://doi.org/10.1021/ acsenergylett.8b02051
- 131. B.E. Cohen, Y. Li, Q. Meng, L. Etgar, Dion-jacobson twodimensional perovskite solar cells based on benzene dimethanammonium cation. Nano Lett. **19**(4), 2588–2597 (2019). https://doi.org/10.1021/acs.nanolett.9b00387

- 132. C. Ma, D. Shen, T.W. Ng, M.F. Lo, C.S. Lee, 2D perovskites with short interlayer distance for high-performance solar cell application. Adv. Mater. 30(22), 1800710–1800715 (2018). https://doi.org/10.1002/adma.201800710
- C.C. Stoumpos, L. Mao, C.D. Malliakas, M.G. Kanatzidis, Structure-bandgap relationships in hexagonal polytypes and low-dimensional structures of hybrid tin iodide perovskites. Inorg. Chem. 56(1), 56–73 (2017). https://doi.org/10.1021/ acs.inorgchem.6b02764
- 134. G. Kieslich, S. Sun, A.K. Cheetham, Solid-state principles applied to organic-inorganic perovskites: new tricks for an old dog. Chem. Sci. 5(12), 4712–4715 (2014). https://doi. org/10.1039/c4sc02211d
- 135. X. Jiang, F. Wang, Q. Wei, H. Li, Y. Shang et al., Ultra-high open-circuit voltage of tin perovskite solar cells via an electron transporting layer design. Nat. Commun. 11(1), 1245– 1251 (2020). https://doi.org/10.1038/s41467-020-15078-2
- 136. C. Wang, F. Gu, Z. Zhao, H. Rao, Y. Qiu et al., Self-repairing tin-based perovskite solar cells with a breakthrough efficiency over 11. Adv. Mater. 32(31), e1907623–e1907631 (2020). https://doi.org/10.1002/adma.201907623
- 137. F. Hao, C.C. Stoumpos, R.P.H. Chang, M.G. Kanatzidis, Anomalous bandgap behavior in mixed Sn and Pb perovskites enables broadening of absorption spectrum in solar cells. J. Am. Chem. Soc. 136(22), 8094–8099 (2014). https://doi. org/10.1021/ja5033259
- H.D. Kim, Y. Miyamoto, H. Kubota, T. Yamanari, H. Ohkita, Open-circuit voltage loss in CH<sub>3</sub>NH<sub>3</sub>SnI<sub>3</sub> perovskite solar cells. Chem. Lett. 46, 253–256 (2017). https://doi. org/10.1246/cl.160994
- 139. T. Handa, T. Yamada, H. Kubota, S. Ise, Y. Miyamoto et al., Photocarrier recombination and injection dynamics in longterm stable lead-free CH<sub>3</sub>NH<sub>3</sub>SnI<sub>3</sub> perovskite thin films and solar cells. J. Phys. Chem. C **121**(30), 16158–16165 (2017). https://doi.org/10.1021/acs.jpcc.7b06199
- 140. W. Ke, P. Priyanka, S. Vegiraju, C.C. Stoumpos, I. Spanopoulos et al., Dopant-free tetrakis-triphenylamine hole transporting material for efficient tin-based perovskite solar cells. J. Am. Chem. Soc. **140**(1), 388–393 (2018). https://doi. org/10.1021/jacs.7b10898
- 141. T. Yokoyama, T.-B. Song, D.H. Cao, C.C. Stoumpos, S. Aramaki et al., The origin of lower hole carrier concentration in methylammonium tin halide films grown by a vapor-assisted solution process. ACS Energy Lett. 2(1), 22–28 (2016). https ://doi.org/10.1021/acsenergylett.6b00513
- 142. S.A. Moyez, S. Roy, Thermal engineering of lead-free nanostructured CH<sub>3</sub>NH<sub>3</sub>SnCl<sub>3</sub> perovskite material for thin-film solar cell. J. Nanopart. Res. 20(1), 5–17 (2017). https://doi. org/10.1007/s11051-017-4108-z
- 143. N. Wang, Y. Zhou, M.-G. Ju, H.F. Garces, T. Ding et al., Heterojunction-depleted lead-free perovskite solar cells with coarse-grained b-γ-CsSnI<sub>3</sub> thin films. Adv. Energy Mater. 6(24), 1601130–1601139 (2016). https://doi.org/10.1002/ aenm.201601130
- 144. T.B. Song, T. Yokoyama, C.C. Stoumpos, J. Logsdon, D.H. Cao et al., Importance of reducing vapor atmosphere in the

fabrication of tin-based perovskite solar cells. J. Am. Chem. Soc. **139**(2), 836–842 (2017). https://doi.org/10.1021/jacs.6b10734

- 145. B. Zhao, M. Abdi-Jalebi, M. Tabachnyk, H. Glass, V.S. Kamboj et al., High open-circuit voltages in tin-rich lowbandgap perovskite-based planar heterojunction photovoltaics. Adv. Mater. 29(2), 1604744–1604751 (2017). https://doi. org/10.1002/adma.201604744
- 146. S. Shao, J. Liu, G. Portale, H.-H. Fang, G.R. Blake et al., Highly reproducible Sn-based hybrid perovskite solar cells with 9% efficiency. Adv. Energy Mater. 8(4), 1702019– 1702028 (2018). https://doi.org/10.1002/aenm.201702019
- 147. L.-J. Chen, C.-R. Lee, Y.-J. Chuang, Z.-H. Wu, C. Chen, Synthesis and optical properties of lead-free cesium tin halide perovskite quantum rods with high-performance solar cell application. J. Phys. Chem. Lett. 7(24), 5028–5035 (2016). https://doi.org/10.1021/acs.jpclett.6b02344
- 148. J. Xi, Z. Wu, B. Jiao, H. Dong, C. Ran et al., Multichannel interdiffusion driven FASnI<sub>3</sub> film formation using aqueous hybrid salt/polymer solutions toward flexible lead-free perovskite solar cells. Adv. Mater. **29**(23), 1606964–1606970 (2017). https://doi.org/10.1002/adma.201606964
- 149. D. Moghe, L. Wang, C.J. Traverse, A. Redoute, M. Sponseller et al., All vapor-deposited lead-free doped CsSnBr 3 planar solar cells. Nano Energy 28, 469–474 (2016). https:// doi.org/10.1016/j.nanoen.2016.09.009
- C. Ran, J. Xi, W. Gao, F. Yuan, T. Lei et al., Bilateral interface engineering toward efficient 2D-3D bulk heterojunction tin halide lead-free perovskite solar cells. ACS Energy Lett. 3(3), 713–721 (2018). https://doi.org/10.1021/acsenergyl ett.8b00085
- 151. Y. Yu, D. Zhao, C.R. Grice, W. Meng, C. Wang et al., Thermally evaporated methylammonium tin triiodide thin films for lead-free perovskite solar cell fabrication. RSC Adv. 6(93), 90248–90254 (2016). https://doi.org/10.1039/c6ra1 9476a
- 152. C.-M. Tsai, N. Mohanta, C.-Y. Wang, Y.-P. Lin, Y.-W. Yang et al., Formation of stable tin perovskites co-crystallized with three halides for carbon-based mesoscopic lead-free perovskite solar cells. Angew. Chem. Int. Ed. 56(44), 13819–13823 (2017). https://doi.org/10.1002/anie.201707037
- 153. W. Li, J. Li, J. Ean, Y. Maib et al., Addictive-assisted construction of all-inorganic CsSnIBr 2 mesoscopic perovskite solar cells with superior thermal stability up to 473 K. J. Mater. Chem. A 4, 17104–17110 (2016). https://doi. org/10.1039/c6ta08332c
- 154. K. Chen, P. Wu, W. Yang, R. Su, D. Luo et al., Lowdimensional perovskite interlayer for highly efficient leadfree formamidinium tin iodide perovskite solar cells. Nano Energy 49, 411–418 (2018). https://doi.org/10.1016/j.nanoe n.2018.05.006
- 155. E. Jokar, C.-H. Chien, A. Fathi, M. Rameez, C.-Y. Hao et al., Slow surface passivation and crystal relaxation with additives to improve device performance and durability for tinbased perovskite solar cells. Energy Environ. Sci. 11(9), 1–12 (2018). https://doi.org/10.1039/C8EE00956B

- 156. X.Y. Meng, Y.B. Wang, J.B. Lin, X. Liu, X. He et al., Surface-controlled oriented growth of FASnI<sub>3</sub> crystals for efficient lead-free perovskite solar cells. Joule 4, 902–912 (2020). https://doi.org/10.1016/j.joule.2020.03.007
- 157. L.-C. Tang, C.-S. Chang, J.Y. Huang, Electronic structure and optical properties of rhombohedral CsGeI<sub>3</sub> crystal. J. Phys.: Condens. Matter **12**(43), 9129–9143 (2000). https:// doi.org/10.1088/0953-8984/12/43/303
- 158. I. Kopacic, B. Friesenbichler, S.F. Hoefler, B. Kunert, H. Plank et al., Enhanced performance of germanium halide perovskite solar cells through compositional engineering. ACS Appl. Energy Mater. 1(2), 343–347 (2018). https://doi. org/10.1021/acsaem.8b00007
- 159. M.F. Mostafa, R.D. Willett, Magnetic properties of ferrous chloride complexes with two-dimensional structures. Phys. Rev. B 4(7), 2213–2215 (1971). https://doi.org/10.1103/ PhysRevB.4.2213
- 160. S.N. Ruddlesden, P. Popper, New compounds of the K<sub>2</sub>NiF<sub>4</sub> type. Acta Cryst. **10**(8), 538–539 (1957). https://doi. org/10.1107/S0365110X57001929
- 161. X.-P. Cui, K.-J. Jiang, J.-H. Huang, Q.-Q. Zhang, M.-J. Su et al., Cupric bromide hybrid perovskite heterojunction solar cells. Synth. Met. 209, 247–250 (2015). https://doi. org/10.1016/j.synthmet.2015.07.013
- 162. X. Li, B. Li, J. Chang, B. Ding, S. Zheng et al., (C6H5CH2NH3)2CuBr 4: a lead-free, highly stable twodimensional perovskite for solar cell applications. ACS Appl. Energy Mater. 1(6), 2709–2716 (2018). https://doi. org/10.1021/acsaem.8b00372
- M. Abulikemu, S. Ould-Chikh, X. Miao, E. Alarousu, B. Murali et al., Optoelectronic and photovoltaic properties of the air-stable organohalide semiconductor (CH<sub>3</sub>NH<sub>3</sub>)<sub>3</sub>Bi<sub>2</sub>I<sub>9</sub>.
   J. Mater. Chem. A 4(32), 12504–12515 (2016). https://doi. org/10.1039/c6ta04657f
- 164. R.L.Z. Hoye, R.E. Brandt, A. Osherov, V. Stevanović, S.D. Stranks et al., Methylammonium bismuth iodide as a leadfree, stable hybrid organic-inorganic solar absorber. Chem. Eur. J. 22(8), 2605–2610 (2016). https://doi.org/10.1002/ chem.201505055
- 165. Z. Zhang, X. Li, X. Xia, Z. Wang, Z. Huang et al., High-quality (CH<sub>3</sub>NH<sub>3</sub>)<sub>3</sub>Bi<sub>2</sub>I<sub>9</sub> film-based solar cells: pushing efficiency up to 1.64. J. Phys. Chem. Lett. 8(17), 4300–4307 (2017). https://doi.org/10.1021/acs.jpclett.7b01952
- 166. C. Ran, Z. Wu, J. Xi, F. Yuan, H. Dong et al., Construction of compact methylammonium bismuth iodide film promoting lead-free inverted planar heterojunction organohalide solar cells with open-circuit voltage over 0.8 V. J. Phys. Chem. Lett. 8(2), 394–400 (2017). https://doi.org/10.1021/acs.jpcle tt.6b02578
- 167. M.B. Johansson, H. Zhu, E.M. Johansson, Extended photoconversion spectrum in low-toxic bismuth halide perovskite solar cells. J. Phys. Chem. Lett. 7(17), 3467–3471 (2016). https://doi.org/10.1021/acs.jpclett.6b01452
- 168. A.K. Baranwal, H. Masutani, H. Sugita, H. Kanda, S. Kanaya et al., Lead-free perovskite solar cells using Sb and Bi-based A<sub>3</sub>B<sub>2</sub>X<sub>9</sub> and A<sub>3</sub>BX<sub>6</sub> crystals with normal and inverse cell

structures. Nano Converg. **4**(1), 26–39 (2017). https://doi. org/10.1186/s40580-017-0120-3

- 169. M. Lyu, J.-H. Yun, M. Cai, Y. Jiao, P.V. Bernhardt et al., Organic-inorganic bismuth (III)-based material: a lead-free, air-stable and solution-processable light-absorber beyond organolead perovskites. Nano Res. 9(3), 692–702 (2016). https://doi.org/10.1007/s12274-015-0948-y
- 170. S.S. Shin, O.P.C. Baena, O.C. Kurchin, O. Polizzotti, O.J. Yoo et al., Solvent-engineering method to deposit compact bismuth-based thin films: mechanism and application to photovoltaics. Chem. Mater. **30**(2), 336–343 (2018). https://doi. org/10.1021/acs.chemmater.7b03227
- 171. S.M. Jain, D. Phuyal, M.L. Davies, M. Li, B. Philippe et al., An effective approach of vapour assisted morphological tailoring for reducing metal defect sites in leadfree, (CH<sub>3</sub>NH<sub>3</sub>)<sub>3</sub>Bi<sub>2</sub>I<sub>9</sub> bismuth-based perovskite solar cells for improved performance and long-term stability. Nano Energy **49**, 614–624 (2018). https://doi.org/10.1016/j.nanoe n.2018.05.003
- 172. F. Bai, Y. Hu, Y. Hu, T. Qiu, X. Miao et al., Lead-free, airstable ultrathin Cs<sub>3</sub>Bi<sub>2</sub>I<sub>9</sub> perovskite nanosheets for solar cells. Sol. Energy Mater. Sol. Cells **184**, 15–21 (2018). https://doi. org/10.1016/j.solmat.2018.04.032
- 173. J.-C. Hebig, I. Kühn, J. Flohre, T. Kirchartz, Optoelectronic properties of (CH<sub>3</sub>NH<sub>3</sub>)<sub>3</sub>Sb<sub>2</sub>I<sub>9</sub> thin films for photovoltaic applications. ACS Energy Lett. 1(1), 309–314 (2016). https ://doi.org/10.1021/acsenergylett.6b00170
- 174. P.C. Harikesh, H.K. Mulmudi, B. Ghosh, T.W. Goh, Y.T. Teng et al., Rb as an alternative cation for templating inorganic lead-free perovskites for solution processed photovoltaics. Chem. Mater. 28(20), 7496–7504 (2016). https://doi. org/10.1021/acs.chemmater.6b03310
- 175. C. Zuo, L. Ding, Lead-free perovskite materials (NH4)3Sb2IxBr 9-x. Angew. Chem. Int. Ed. 56(23), 6528– 6532 (2017). https://doi.org/10.1002/anie.201702265
- 176. F. Jiang, D. Yang, Y. Jiang, T. Liu, X. Zhao et al., Chlorineincorporation-induced formation of the layered phase for antimony-based lead-free perovskite solar cells. J. Am. Chem. Soc. 140(3), 1019–1027 (2018). https://doi.org/10.1021/ jacs.7b10739
- 177. W. Shockley, H.J. Queisser, Detailed balance limit of efficiency of p-n junction solar cells. J. Appl. Phys. 32(3), 510– 519 (1961). https://doi.org/10.1063/1.1736034
- 178. T. Li, X. Wang, Y. Yan, D.B. Mitzi, Phase stability and electronic structure of prospective sb-based mixed sulfide and iodide 3D perovskite (CH<sub>3</sub>NH<sub>3</sub>)SbSI<sub>2</sub>. J. Phys. Chem. Lett. 9(14), 3829–3833 (2018). https://doi.org/10.1021/acs.jpclett.8b01641
- 179. A. Antonio, Perovskite solar cells go lead free. Joule 1(4), 659–664 (2017). https://doi.org/10.1016/j.joule.2017.09.007
- 180. Y. Cai, W. Xie, H. Ding, Y. Chen, T. Krishnamoorthy et al., Computational study of halide perovskite-derived A<sub>2</sub>BX<sub>6</sub> inorganic compounds: chemical trends in electronic structure and structural stability. Chem. Mater. **29**(18), 7740 (2017). https://doi.org/10.1021/acs.chemmater.7b02013

- A.E. Maughan, J.A. Kurzman, J.R. Neilson, Hybrid inorganic-organic materials with an optoelectronically active aromatic cation: (C<sub>7</sub>H<sub>7</sub>)<sub>2</sub>SnI<sub>6</sub> and C<sub>7</sub>H<sub>7</sub>PbI<sub>3</sub>. Inorg. Chem. 54(1), 370–378 (2015). https://doi.org/10.1021/ic5025795
- 182. M.M. Elsenety, A. Kaltzoglou, M. Antoniadou, I. Koutselas, A.G. Kontos et al., Synthesis, characterization and use of highly stable trimethyl sulfonium tin(IV) halide defect perovskites in dye sensitized solar cells. Polyhedron **150**, 83–91 (2018). https://doi.org/10.1016/j.poly.2018.05.001
- 183. X. Qiu, Y. Jiang, H. Zhang, Z. Qiu, S. Yuan et al., Lead-free mesoscopic Cs<sub>2</sub>SnI<sub>6</sub> perovskite solar cells using different nanostructured ZnO nanorods as electron transport layers. Phys. Status Solid. RRL **10**(8), 587–591 (2016). https://doi. org/10.1002/pssr.201600166
- 184. B. Lee, A. Krenselewski, S. Il-Baik, D. Seidman, R.P.H. Chang, Solution processing of air-stable molecular semiconducting iodosalts, Cs<sub>2</sub>SnI<sub>6-x</sub>Br<sub>x</sub>, for potential solar cell applications. Sustain. Energy Fuels 1(4), 710–724 (2017). https://doi.org/10.1039/c7se00100b
- 185. A.E. Maughan, A.M. Ganose, M.M. Bordelon, E.M. Miller, D.O. Scanlon et al., Defect tolerance to intolerance in the vacancy-ordered double perovskite semiconductors Cs<sub>2</sub>SnI<sub>6</sub> and Cs<sub>2</sub>TeI<sub>6</sub>. J. Am. Chem. Soc. **138**(27), 8453–8464 (2016). https://doi.org/10.1021/jacs.6b03207
- 186. M. Chen, M.-G. Ju, A.D. Carl, Y. Zong, R.L. Grimm et al., Cesium titanium(IV) bromide thin films based stable leadfree perovskite solar cells. Joule 2(3), 558–570 (2018). https ://doi.org/10.1016/j.joule.2018.01.009
- 187. E. Greul, M.L. Petrus, A. Binek, P. Docampo, T. Bein, Highly stable, phase pure Cs2AgBiBr 6 double perovskite thin films for optoelectronic applications. J. Mater. Chem. A 5(37), 19972–19981 (2017). https://doi.org/10.1039/c7ta06816f

- 188. C. Wu, Q. Zhang, Y. Liu, W. Luo, X. Guo et al., The dawn of lead-free perovskite solar cell: highly stable double perovskite Cs2AgBiBr 6 film. Adv. Sci. 5(3), 1700759–1700766 (2018). https://doi.org/10.1002/advs.201700759
- 189. W. Gao, C. Ran, J. Xi, B. Jiao, W. Zhang et al., High-quality Cs2AgBiBr 6 double perovskite film for lead-free inverted planar heterojunction solar cells with 2@2% efficiency. ChemPhysChem 19(14), 1696–1700 (2018). https://doi. org/10.1002/cphc.201800346
- 190. M. Pantaler, K.T. Cho, V. Queloz, I.G. Benito, C. Fettkenhauer et al., Hysteresis-free lead-free double perovskite solar cells by interface engineering. ACS Energy Lett. 3, 1781– 1786 (2018). https://doi.org/10.1021/acsenergylett.8b00871
- 191. M. Wang, P. Zeng, S. Bai, J. Gu, F. Li et al., High quality sequential-vapor-deposited Cs2AgBiBr 6 thin films for lead-free perovskite solar cells. Sol. RRL. 2(12), 1800217– 1800222 (2018). https://doi.org/10.1002/solr.201800217
- 192. P. Li, W. Gao, C. Ran, H. Dong, X. Hou et al., Post-treatment engineering of vacuum-deposited  $Cs_2NaBiI_6$  double perovskite film for enhanced photovoltaic performance. Phys. Status Solidi A **216**(23), 1900567–1900574 (2019). https://doi.org/10.1002/pssa.201900567
- 193. H. Wang, Y. Zhao, Z. Wang, Y. Liu, Z. Zhao et al., Hermetic seal for perovskite solar cells: an improved plasma enhanced atomic layer deposition encapsulation. Nano Energy 69, 104375–104383 (2020). https://doi.org/10.1016/j.nanoe n.2019.104375
- 194. C. Chen, T.H. Han, S. Tan, J. Xue, Y. Zhao et al., Efficient flexible inorganic perovskite light-emitting diodes fabricated with CsPbBr 3 emitters prepared via low-temperature in situ dynamic thermal crystallization. Nano Lett. 20(6), 4673– 4680 (2020). https://doi.org/10.1021/acs.nanolett.0c01550